

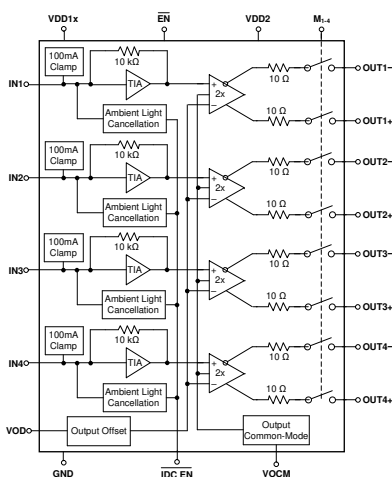
LMH32404 具有集成式钳位和环境光消除功能的四通道、差分输出、多路复用跨阻放大器

1 特性

- 增益：20k Ω
- 性能， $C_{PD} = 1\text{pF}$ ：
 - 带宽：350 MHz
 - 输入参考噪声：56nA_{RMS}
 - 上升，下降时间：1.25ns
- 静态电流：28 mA/通道
- 待机模式：10 mA/通道
- 低功耗模式：2.5mA (4 个通道)
- 通道开关时间：10ns
- 集成式环境光消除
- 集成式 100mA 保护钳位
- 4 个输入通道和 4 个差分输出通道
- 集成的多路复用器可实现光学传感器和 ADC/TDC 之间的灵活配置
- 可以将多个 LMH32404 并联组合，以实现更宽的视野 (FoV)
- 封装：28 引脚 VQFN
 - 裸片 (预览)
- 温度范围：-40°C 至 +125°C

2 应用

- 机械扫描激光雷达
- 固态扫描激光雷达
- 激光测距仪
- 安全区域扫描仪



简化版方框图

3 说明

LMH32404 是一款四通道、单端输入转差分输出跨阻放大器 (TIA)，适用于光探测和测距 (LIDAR) 应用和激光测距系统。

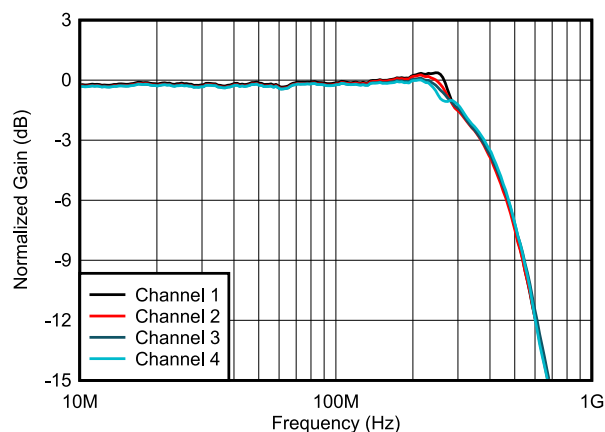
LMH32404 在每个通道上集成了一个 100mA 钳位，可以为放大器提供保护并允许器件迅速从过载输入状况中恢复。LMH32404 还在每个通道上提供一个集成式环境光消除 (ALC) 电路，可取代光电二极管与放大器之间的交流耦合，从而节省布板空间和系统成本。进行直流和低频测量时，应禁用 ALC 回路。

每个 LMH32404 通道在输出端具有集成的开关，用于断开差分输出放大器与输出引脚的连接，并将通道置于待机模式。在不同通道之间切换时，转换时间仅为 10ns。当不使用放大器时，可以使用 $\overline{\text{EN}}$ 引脚将 LMH32404 置于低功耗模式，以节省能源。

器件信息(1)

| 器件型号 | 封装 | 封装尺寸 (标称值) |
|----------|-----------|---------------------|
| LMH32404 | VQFN (28) | 5.00mm × 4.00mm |
| | 裸片(2) | 1.346 mm × 2.455 mm |

- 如需了解所有可用封装，请参阅产品说明书末尾的封装选项附录。
- 预发布封装。



闭环带宽



Table of Contents

| | | | |
|---|-----------|--|-----------|
| 1 特性 | 1 | 7.4 Device Functional Modes..... | 22 |
| 2 应用 | 1 | 8 Application and Implementation | 25 |
| 3 说明 | 1 | 8.1 Application Information..... | 25 |
| 4 Revision History | 2 | 8.2 Typical Application..... | 27 |
| 5 Pin Configuration and Functions | 3 | 9 Power Supply Recommendations | 30 |
| 6 Specifications | 7 | 10 Layout | 31 |
| 6.1 Absolute Maximum Ratings..... | 7 | 10.1 Layout Guidelines..... | 31 |
| 6.2 ESD Ratings..... | 7 | 10.2 Layout Example..... | 31 |
| 6.3 Recommended Operating Conditions..... | 7 | 11 Device and Documentation Support | 32 |
| 6.4 Thermal Information..... | 7 | 11.1 Device Support..... | 32 |
| 6.5 Electrical Characteristics..... | 8 | 11.2 Documentation Support..... | 32 |
| 6.6 Electrical Characteristics: Logic Threshold and Switching Characteristics..... | 11 | 11.3 Receiving Notification of Documentation Updates.. | 32 |
| 6.7 Typical Characteristics..... | 12 | 11.4 支持资源..... | 32 |
| 7 Detailed Description | 18 | 11.5 Trademarks..... | 32 |
| 7.1 Overview..... | 18 | 11.6 Electrostatic Discharge Caution..... | 32 |
| 7.2 Functional Block Diagram..... | 19 | 11.7 术语表..... | 32 |
| 7.3 Feature Description..... | 20 | 12 Mechanical, Packaging, and Orderable Information | 32 |

4 Revision History

注：以前版本的页码可能与当前版本的页码不同

| Changes from Revision A (November 2021) to Revision B (February 2022) | Page |
|--|-------------|
| • 向特性部分和器件信息表添加了裸片预发布封装 | 1 |
| • Added the <i>bare die preview package</i> to the <i>Pin Configuration and Functions</i> section..... | 3 |

| Changes from Revision * (August 2021) to Revision A (November 2021) | Page |
|--|-------------|
| • Updated the JEDEC reference in the <i>ESD Ratings</i> table from <i>JESD22-C101</i> to <i>JEDEC JS-002</i> | 7 |
| • Updated the <i>Overview</i> section..... | 18 |
| • Updated the <i>Clamping and Input Protection</i> section..... | 20 |
| • Updated the <i>Differential Output Stage</i> section..... | 20 |
| • Updated the <i>Ambient Light Cancellation (ALC) Mode</i> section..... | 22 |

5 Pin Configuration and Functions

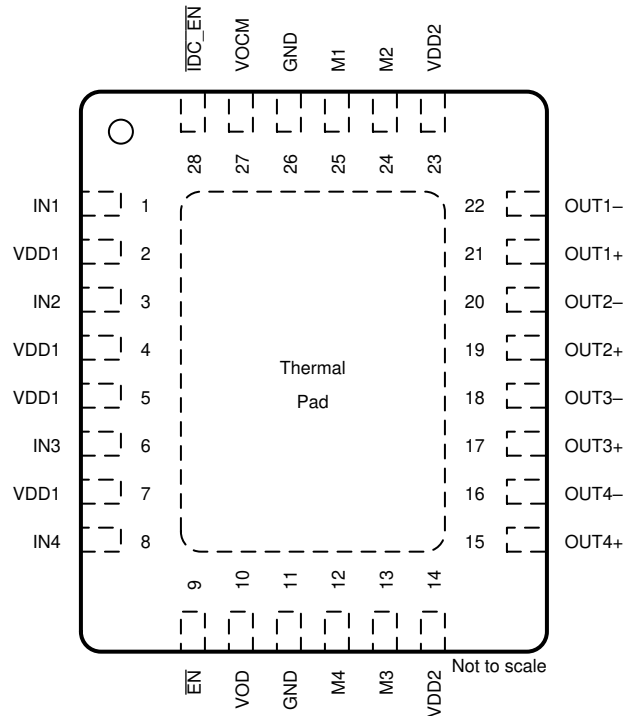


图 5-1. RHF Package, 28-Pin VQFN, (Top View)

表 5-1. Pin Functions

| PIN | | TYPE ⁽²⁾ | DESCRIPTION |
|--------|--------|---------------------|---|
| NAME | NO. | | |
| EN | 9 | I | Device enable pin. EN = logic low = normal operation (default); EN = logic high = low power mode. ⁽¹⁾ |
| GND | 11, 26 | I | Amplifier ground. |
| IDC_EN | 28 | I | Ambient light cancellation loop enable. IDC_EN = logic low = enable DC cancellation (default); IDC_EN = logic high = disable DC cancellation. ⁽¹⁾ |
| IN1 | 1 | I | Transimpedance amplifier input - Channel 1. |
| IN2 | 3 | I | Transimpedance amplifier input - Channel 2. |
| IN3 | 6 | I | Transimpedance amplifier input - Channel 3. |
| IN4 | 8 | I | Transimpedance amplifier input - Channel 4. |
| M1 | 25 | I | Select Channel 1. M1 = logic high = Channel 1 operational and output switches closed. M1 = logic low (default) = Channel 1 in standby power mode and output switches open. ⁽¹⁾ |
| M2 | 24 | I | Select Channel 2. M2 = logic high = Channel 2 operational and output switches closed. M2 = logic low (default) = Channel 2 in standby power mode and output switches open. ⁽¹⁾ |
| M3 | 13 | I | Select Channel 3. M3 = logic high = Channel 3 operational and output switches closed. M3 = logic low (default) = Channel 3 in standby power mode and output switches open. ⁽¹⁾ |
| M4 | 12 | I | Select Channel 4. M4 = logic high = Channel 4 operational and output switches closed. M4 = logic low (default) = Channel 4 in standby power mode and output switches open. ⁽¹⁾ |
| OUT1 - | 22 | O | Channel 1 inverting amplifier output. When light is incident on the photodiode the output pin transitions in a negative direction from the no light condition. |
| OUT1+ | 21 | O | Channel 1 noninverting amplifier output. When light is incident on the photodiode the output pin transitions in a positive direction from the no light condition. |
| OUT2 - | 20 | O | Channel 2 inverting amplifier output. When light is incident on the photodiode the output pin transitions in a negative direction from the no light condition. |
| OUT2+ | 19 | O | Channel 2 noninverting amplifier output. When light is incident on the photodiode the output pin transitions in a positive direction from the no light condition. |

表 5-1. Pin Functions (continued)

| PIN | | TYPE ⁽²⁾ | DESCRIPTION |
|-------------|------------|---------------------|---|
| NAME | NO. | | |
| OUT3 – | 18 | O | Channel 3 inverting amplifier output. When light is incident on the photodiode the output pin transitions in a negative direction from the no light condition. |
| OUT3+ | 17 | O | Channel 3 noninverting amplifier output. When light is incident on the photodiode the output pin transitions in a positive direction from the no light condition. |
| OUT4 – | 16 | O | Channel 4 inverting amplifier output. When light is incident on the photodiode the output pin transitions in a negative direction from the no light condition. |
| OUT4+ | 15 | O | Channel 4 noninverting amplifier output. When light is incident on the photodiode the output pin transitions in a positive direction from the no light condition. |
| VDD1 | 2, 4, 5, 7 | I | Positive power supply for the transimpedance amplifier stage. Each pin should be tied to the same power supply with independent power-supply bypassing. |
| VDD2 | 14, 23 | I | Positive power supply for the differential amplifier stage. Tie VDD1 and VDD2 to the same power supply with independent power-supply bypassing. |
| VOCM | 27 | I | Differential amplifier common-mode output control. |
| VOD | 10 | I | Differential amplifier differential output offset control. |
| Thermal pad | | — | Connect the thermal pad to the same potential as pin 11 and 26 (GND). |

- (1) TI recommends driving a digital pin with a low-impedance source rather than leaving the pin floating because fast-moving transients can couple into the pin and inadvertently change the logic level.
- (2) I = input, O = output

| DIE THICKNESS | BACKSIDE FINISH | BACKSIDE POTENTIAL | BOND PAD METALLIZATION |
|-------------------|------------------------|---|------------------------|
| 267 μm | Silicon with backgrind | Wafer backside is electrically isolated from active circuitry | AlCu |

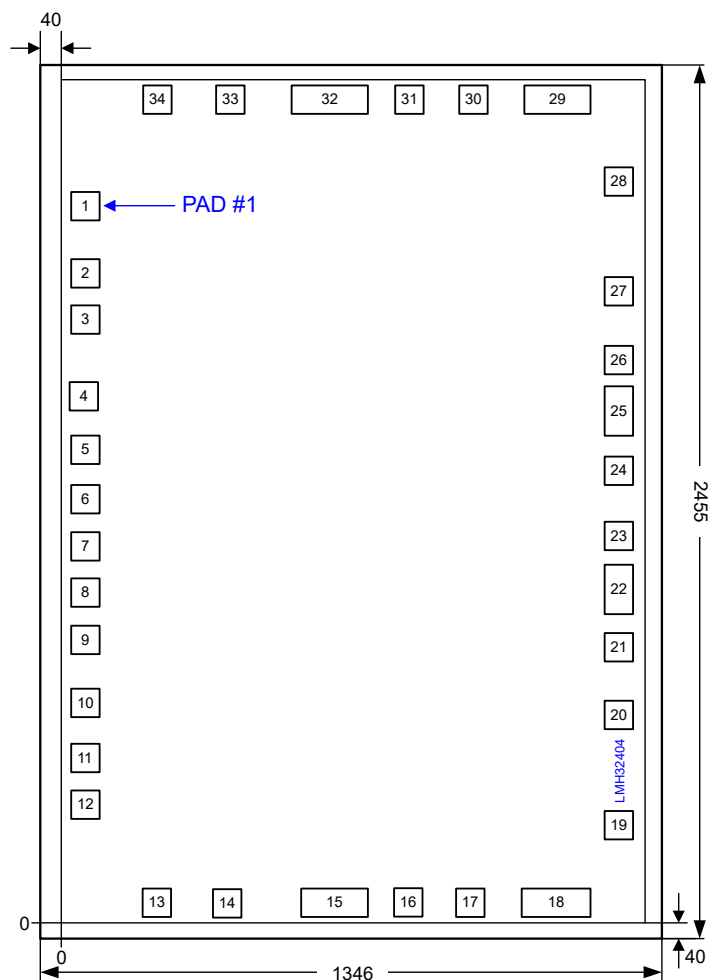


图 5-2. Bare Die Package (Preview)

表 5-2. Bond Pad Coordinates of YS package in Microns

| PAD NUMBER | PAD NAME | X-MIN | Y-MIN | X-MAX | Y-MAX |
|------------|----------|---------|----------|---------|----------|
| 1 | IN1 | 15 | 1981.075 | 90 | 2056.075 |
| 2 | VDD2 | 15 | 1795.225 | 90 | 1870.225 |
| 3 | GND | 15 | 1663.3 | 90 | 1738.3 |
| 4 | IN2 | 15 | 1450.675 | 90 | 1525.675 |
| 5 | VDD2 | 15 | 1295.225 | 90 | 1370.225 |
| 6 | GND | 15 | 1163.3 | 90 | 1238.3 |
| 7 | VDD2 | 15 | 1026.65 | 90 | 1101.65 |
| 8 | IN3 | 15 | 898.55 | 90 | 973.55 |
| 9 | GND | 15 | 766.475 | 90 | 841.475 |
| 10 | GND | 15 | 590.775 | 90 | 665.775 |
| 11 | VDD2 | 15 | 435.325 | 90 | 510.325 |
| 12 | IN4 | 15 | 301.75 | 90 | 376.75 |
| 13 | EN | 172.675 | 15 | 247.675 | 90 |

表 5-2. Bond Pad Coordinates of YS package in Microns (continued)

| PAD NUMBER | PAD NAME | X-MIN | Y-MIN | X-MAX | Y-MAX |
|------------|----------|----------|---------|----------|---------|
| 14 | VOD | 329.35 | 15 | 404.35 | 90 |
| 15 | GND | 522.85 | 15 | 672.85 | 90 |
| 16 | M4 | 718.525 | 15 | 793.525 | 90 |
| 17 | M3 | 857.95 | 15 | 932.95 | 90 |
| 18 | VDD2 | 1001.725 | 15 | 1151.725 | 90 |
| 19 | OUT4+ | 1176 | 244.2 | 1251 | 319.2 |
| 20 | OUT4 - | 1176 | 552.2 | 1251 | 627.2 |
| 21 | OUT3+ | 1176 | 744.2 | 1251 | 819.2 |
| 22 | GND | 1176 | 864.45 | 1251 | 1014.45 |
| 23 | OUT3 - | 1176 | 1052.2 | 1251 | 1127.2 |
| 24 | OUT2+ | 1176 | 1244.2 | 1251 | 1319.2 |
| 25 | GND | 1176 | 1364.45 | 1251 | 1514.45 |
| 26 | OUT2 - | 1176 | 1552.2 | 1251 | 1627.2 |
| 27 | OUT1+ | 1176 | 1744.2 | 1251 | 1819.2 |
| 28 | OUT1 - | 1176 | 2052.2 | 1251 | 2127.2 |
| 29 | VDD2 | 1001.725 | 2285 | 1151.725 | 2360 |
| 30 | M2 | 857.95 | 2285 | 932.95 | 2360 |
| 31 | M1 | 718.525 | 2285 | 793.525 | 2360 |
| 32 | GND | 497.85 | 2285 | 672.85 | 2360 |
| 33 | VOCM | 329.35 | 2285 | 404.35 | 2360 |
| 34 | IDC_EN | 172.675 | 2285 | 247.675 | 2360 |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | MAX | UNIT |
|-------------------------------------|---|-------|-----------------|------|
| V _{DD1} , V _{DD2} | Total supply voltage, (V _{DD}) ⁽²⁾ | | 3.65 | V |
| | Voltage at Output pins | 0 | V _{DD} | V |
| | Voltage at Logic pins | - 0.2 | V _{DD} | V |
| I _{IN} | Continuous current into IN | | 25 | mA |
| I _{OUT} | Continuous output current | | 35 | mA |
| T _J | Junction temperature | | 150 | °C |
| T _A | Operating free-air temperature | - 40 | 125 | °C |
| T _{stg} | Storage temperature | - 65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) VDD1 and VDD2 should always be tied to the same supply and have separate power-supply bypass capacitors.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ | ±1500 | V |
| | | Charged device model (CDM), per JEDEC specification JEDEC JS-002, all pins ⁽²⁾ | ±1000 | |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | NOM | MAX | UNIT |
|-----------------|--------------------------------|------|-----|------|------|
| V _{DD} | Total supply voltage | 3 | 3.3 | 3.45 | V |
| T _A | Operating free-air temperature | - 40 | | 125 | °C |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | LMH32404 | UNIT |
|-------------------------------|--|------------|------|
| | | RHF (VQFN) | |
| | | 28 PINS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 39.7 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 31.5 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 17.8 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 0.8 | °C/W |
| Ψ _{JB} | Junction-to-board characterization parameter | 17.8 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | 6.0 | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

$V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{Open}$, $V_{OD} = 0\text{ V}$, $C_{PD}^{(1)} = 1\text{ pF}$, $\overline{EN} = 0\text{ V}$, $\overline{IDC_EN} = 3.3\text{ V}$, $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$. (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|---|--|------|------|------|-------------------|
| AC PERFORMANCE | | | | | | |
| SSBW | Small-signal bandwidth | V _{OUT} = 100 mV _{PP} | | 350 | | MHz |
| LSBW | Large-signal bandwidth | V _{OUT} = 1 V _{PP} | | 300 | | MHz |
| t _R , t _F | Rise and fall time | V _{OUT} = 100 mV _{PP} , Pulse width = 10 ns | | 1.25 | | ns |
| | Slew Rate ⁽⁴⁾ | V _{OUT} = 1 V _{PP} , Pulse width = 10 ns | | 750 | | V/μs |
| | Overload recovery time (1% settling) | I _{IN} = 100 mA, Pulse width = 10 ns | | 12 | | ns |
| | Overload pulse width extension ⁽⁵⁾ | I _{IN} = 100 mA, Pulse width = 10 ns | | 5 | | ns |
| i _{IN} | Integrated input current noise | f = 250 MHz | | 56 | | nA _{RMS} |
| | Adjacent channel crosstalk | f = 100 MHz | | -49 | | dBc |
| | Non adjacent channel crosstalk | f = 100 MHz | | -58 | | dBc |
| | All hostile channels crosstalk | f = 100 MHz | | -39 | | dBc |
| DC PERFORMANCE | | | | | | |
| Z ₂₁ | Small-signal transimpedance gain ⁽⁶⁾ | | 17 | 20 | 23 | k Ω |
| V _{OD} | Differential output offset voltage (V _{OUT-} - V _{OUT+}) | | - 20 | ±5 | 20 | mV |
| | Differential output offset voltage drift, Δ V _{OD} / Δ T _A | | | ±20 | | μV/°C |
| INPUT PERFORMANCE | | | | | | |
| V _{IN} | Default input bias voltage | Input pin floating | 2.42 | 2.47 | 2.52 | V |
| | Default input bias voltage drift, Δ V _{IN} / Δ T _A | Input pin floating | | 1.1 | | mV/°C |
| I _{IN} | DC Input current range | Z ₂₁ < 3-dB degradation from I _{IN} = 5 μA | 60 | 72 | | μA |
| OUTPUT PERFORMANCE | | | | | | |
| V _{OH} | Single-sided output voltage swing(high) ⁽²⁾ | | 2.85 | 2.9 | | V |
| V _{OL} | Single-sided output voltage swing (low) ⁽²⁾ | | | 0.36 | 0.39 | V |
| I _{OUT} | Linear output drive (sink and source) | T _A = 25°C, I _{IN} = 50 μA , R _L = 25 Ω | 24 | 26.6 | 32 | mA |
| | | T _A = - 40°C, I _{IN} = 50 μA , R _L = 25 Ω | | 27.1 | | |
| | | T _A = 125°C, I _{IN} = 50 μA , R _L = 25 Ω | | 25.1 | | |
| I _{SC} | Output short-circuit current (differential) ⁽³⁾ | | | 70 | | mA |
| Z _{OUT} | DC differential output impedance | M _X = high | 18 | 21 | 24 | Ω |
| | | M _X = low | | 1 | | M Ω |
| OUTPUT COMMON-MODE CONTROL (V _{OCM}) PERFORMANCE | | | | | | |
| SSBW | Small-signal bandwidth | V _{OCM} = 100 mV _{PP} at V _{OCM} pin | | 375 | | MHz |
| LSBW | Large-signal bandwidth | V _{OCM} = 1 V _{PP} at V _{OCM} pin | | 120 | | MHz |
| e _N | Output common-mode noise | f = 10 MHz, 1 nF capacitor to GND on V _{OCM} pin | | 15 | | nV/ √ Hz |
| A _V | Gain, (Δ V _{OCM} / Δ V _{OCM}) | IN floating, V _{OCM} = 1.1 V (driven) | | 1 | | V/V |
| | Gain Error | T _A = 25°C, V _{OCM} = 0.7 V to 2.3 V | - 2% | 0.5% | 2% | |
| | | T _A = - 40°C to 125°C, V _{OCM} = 0.7 V to 2.3 V | | ±1% | | |
| | Input impedance | | | 17 | | k Ω |
| V _{OCM} | V _{OCM} pin default offset from 1.1 V | V _{OCM} floating, (V _{OCM} - 1.1 V) | - 25 | 8 | 45 | mV |
| | V _{OCM} error vs Input current, Δ V _{OCM} / Δ I _{IN} | V _{OCM} driven to 1.1 V | | 10 | | V/A |
| V _{OCM} | Output common-mode voltage, (V _{OUT+} + V _{OUT-})/2 | T _A = 25°C, V _{OCM} floating | 1 | 1.1 | 1.2 | V |

6.5 Electrical Characteristics (continued)

$V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{Open}$, $V_{OD} = 0\text{ V}$, $C_{PD}^{(1)} = 1\text{ pF}$, $\overline{EN} = 0\text{ V}$, $\overline{IDC_EN} = 3.3\text{ V}$, $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$. (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|---|--|------|-------|------|-------|
| | Output common-mode voltage drift, (Δ V _{OCM} /Δ T _A) | T _A = - 40°C to 125°C, V _{OCM} floating | | 300 | | μV/°C |
| V _{OCM} | Output common-mode voltage, (V _{OUT+} + V _{OUT-})/2 | T _A = 25°C, V _{OCM} driven to 1.1V | 1.05 | 1.1 | 1.15 | V |
| | Output common-mode voltage drift, (Δ V _{OCM} /Δ T _A) | T _A = - 40°C to 125°C, V _{OCM} driven to 1.1V | | - 10 | | μV/°C |
| | V _{OCM} headroom to positive supply voltage | T _A = 25°C, V _{OCM} offset shift from V _{OCM} = 1.1 V (driven) < 10-mV | | 1.2 | 1.3 | V |
| | | T _A = - 40°C to 125°C, V _{OCM} offset shift from V _{OCM} = 1.1 V (driven) < 10-mV | | 1 | | V |
| | V _{OCM} headroom to negative supply voltage | T _A = 25°C, V _{OCM} offset shift from V _{OCM} = 1.1 V (driven) < 10-mV | | 0.2 | 0.65 | V |
| | | T _A = - 40°C to 125°C, V _{OCM} offset shift from V _{OCM} = 1.1 V (driven) < 10-mV | | 0.25 | | V |
| OUTPUT DIFFERENTIAL OFFSET (V _{OD}) PERFORMANCE | | | | | | |
| SSBW | Small-signal bandwidth | V _{OD} = 100 mV _{PP} | | 45 | | MHz |
| LSBW | Large-signal bandwidth | V _{OD} = 1 V _{PP} | | 17 | | MHz |
| V _{OD} | Default VOD pin voltage | | | 0.5 | | V |
| V _{OS_D} | Differential output offset, V _{OUT} = (V _{OUT-} - V _{OUT+}) | IN floating, V _{OD} = 0.5 V | 470 | 500 | 530 | mV |
| | Differential output offset drift, Δ V _{OS_D} /Δ T _A | IN floating, V _{OD} = 0.5 V | | 0.03 | | mV/°C |
| V _{OS_D} | Differential output offset, V _{OUT} = (V _{OUT-} - V _{OUT+}) | IN floating, V _{OD} floating | 470 | 500 | 530 | mV |
| | Differential output offset drift, Δ V _{OS_D} /Δ T _A | IN floating, V _{OD} floating | | 0.05 | | mV/°C |
| A _V | Gain, (Δ V _{OUT} /Δ V _{OD}), where V _{OUT} = (V _{OUT-} - V _{OUT+}) | IN floating, V _{OCM} = 1.1 V (driven) | | -1.01 | | V/V |
| | Gain Error | T _A = 25°C, V _{OD} = 0.3 V to 1.2 V | - 5% | ±0.8% | 5% | |
| | | T _A = - 40°C to 125°C, V _{OD} = 0.3 V to 1.2 V | | ±1.5% | | |
| | Input impedance | | | 2.5 | | kΩ |
| AMBIENT LIGHT CANCELLATION PERFORMANCE (IDC_EN = 0 V) ⁽⁷⁾ | | | | | | |
| | Settling time, 1% (2 mV) of settled V _{OS} | I _{IN} = 0 μA → 10 μA | | 20 | | μs |
| | | I _{IN} = 10 μA → 0 μA | | 60 | | |
| | Ambient light current cancellation range | Differential output offset (V _{OUT-} - V _{OUT+}) shift from I _{DC} = 10 μA < 10 mV | 1.8 | 2.5 | | mA |
| POWER SUPPLY | | | | | | |
| I _Q | Quiescent current, per channel, (V _{DD1} + V _{DD2}) | M _X = 3.3 V, T _A = 25°C | 22.8 | 27.7 | 32.5 | mA |
| | | M _X = 0 V, T _A = 25°C | 8.5 | 10.4 | 13.4 | |
| PSRR+ | Positive power-supply rejection ratio | V _{DD1} = V _{DD2} | 54 | 74 | | dB |
| SHUTDOWN | | | | | | |
| I _Q | Total disabled quiescent current (EN = V _{DD}) | T _A = 25°C | | 2.35 | 3 | mA |
| | | T _A = - 40°C | | 2.25 | | |
| | | T _A = 125°C | | 2.55 | | |

- (1) Input capacitance of photodiode.
 (2) Output slammed to the rail and V_{OCM} adjusted to achieve output swing.
 (3) Device cannot withstand continuous short-circuit between the differential outputs.

- (4) Average of rising and falling slew rate.
- (5) Pulse width extension measured at 50% of pulse height of a square wave.
- (6) Gain measured at the amplifier output pins when driving a 100- Ω resistive load. At higher resistor loads the gain will increase.
- (7) Enabling the ambient light cancellation loop will add noise to the system.

6.6 Electrical Characteristics: Logic Threshold and Switching Characteristics

$V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{Open}$, $V_{OD} = 0\text{ V}$, $C_{PD}^{(1)} = 1\text{ pF}$, $\overline{EN} = 0\text{ V}$, $\overline{IDC_EN} = 3.3\text{ V}$, $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$. (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|-----|-----|-----|---------------|
| LOGIC THRESHOLD PERFORMANCE | | | | | |
| Logic pin bias current | | | 75 | 120 | μA |
| \overline{EN} , $\overline{IDC_EN}$, disable threshold voltage | Disabled above this voltage | | 1.5 | 2 | V |
| \overline{EN} , $\overline{IDC_EN}$, enable threshold voltage | Enabled below this voltage | 0.8 | 1 | | V |
| M_X control, enable threshold voltage | Switch closed above this voltage | | 1.5 | 2 | V |
| M_X control, disable threshold voltage | Switch open below this voltage | 0.8 | 1.0 | | V |
| EN CONTROL TRANSIENT PERFORMANCE | | | | | |
| Enable transition-time (1% settling) | Ambient loop disabled, $f_{IN} = 25\text{ MHz}$, $V_{OUT} = 1\text{ V}_{PP}$, $I_{DC} = 0\ \mu\text{A}$ | | 250 | | ns |
| Disable transition-time (1% settling) | Ambient loop disabled, $f_{IN} = 25\text{ MHz}$, $V_{OUT} = 1\text{ V}_{PP}$, $I_{DC} = 0\ \mu\text{A}$ | | 8 | | ns |
| Enable transition-time (1% settling) | Ambient loop enabled, $f_{IN} = 25\text{ MHz}$, $V_{OUT} = 1\text{ V}_{PP}$, $I_{DC} = 100\ \mu\text{A}$ | | 4 | | μs |
| Disable transition-time (1% settling) | Ambient loop enabled, $f_{IN} = 25\text{ MHz}$, $V_{OUT} = 1\text{ V}_{PP}$, $I_{DC} = 100\ \mu\text{A}$ | | 3 | | ns |
| MULTIPLEXER CONTROL TRANSIENT PERFORMANCE | | | | | |
| Channel to Channel transition-time (1% settling) | Ambient loop disabled, $0 \rightarrow 0.5\text{V}$ transition at V_{OUT} | | 10 | | ns |
| Disable transition-time (1% settling) | Ambient loop disabled, $f_{IN} = 25\text{ MHz}$, $V_{OUT} = 1\text{ V}_{PP}$, $I_{DC} = 0\ \mu\text{A}$ | | 8 | | ns |

(1) Input capacitance of photodiode.

6.7 Typical Characteristics

At $V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{open}$, $V_{OD} = 0\text{ V}$, $C_{PD} = 1\text{ pF}$, $\overline{\text{EN}} = 0\text{ V}$ (enabled), $\overline{\text{IDC_EN}} = 3.3\text{ V}$ (disabled), $R_L = 100\ \Omega$ (differential load between $\text{OUT}+$ and $\text{OUT}-$), and $T_A = 25^\circ\text{C}$ (unless otherwise noted)

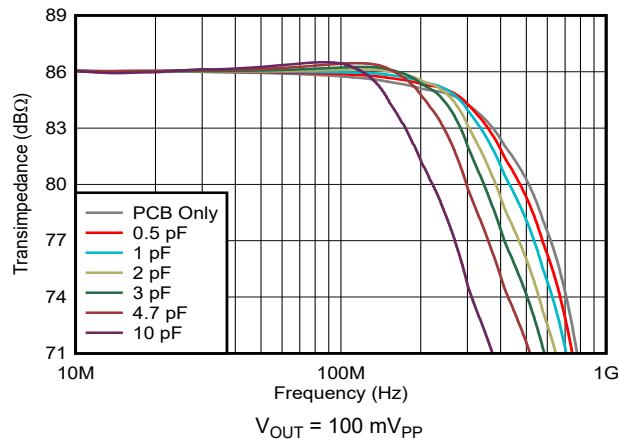


图 6-1. Small Signal Response vs Input Capacitance

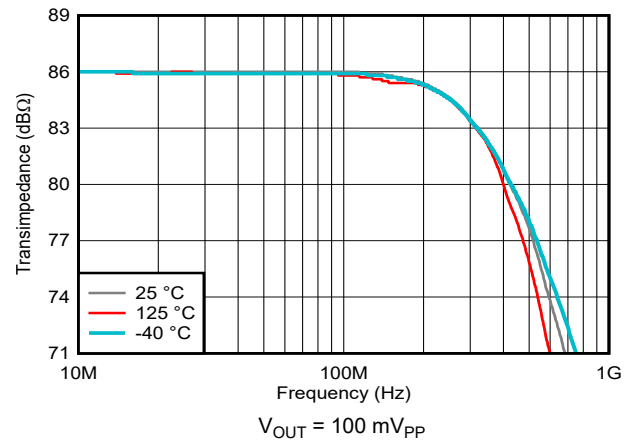


图 6-2. Small Signal Response vs Ambient Temperature

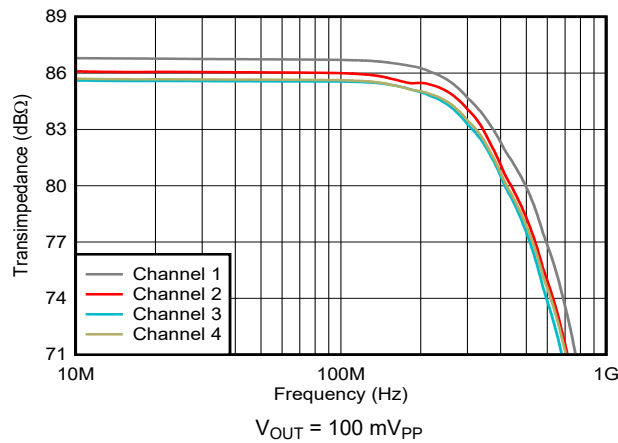


图 6-3. Small Signal Response vs Channels

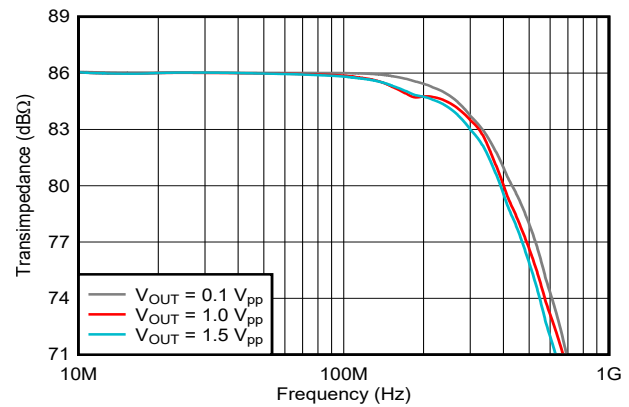


图 6-4. Frequency Response vs Output Swing

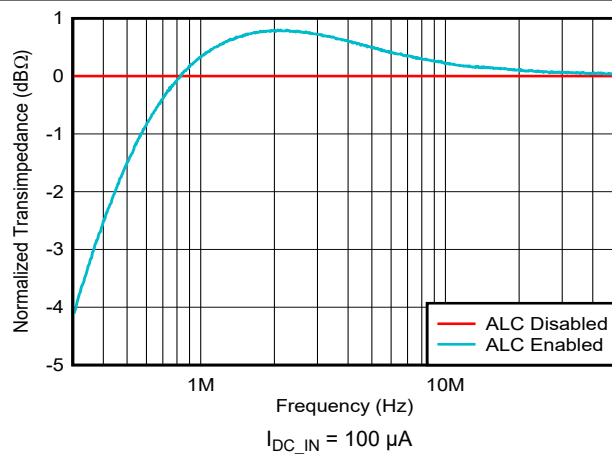


图 6-5. Low-Side Frequency Response vs Ambient Light Cancellation

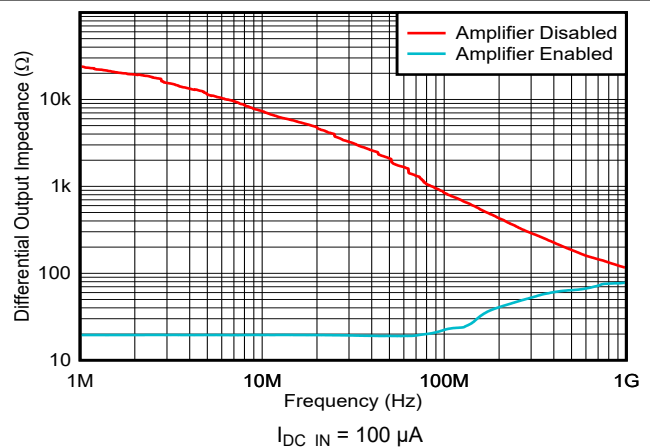


图 6-6. Closed-Loop Output Impedance vs Frequency

6.7 Typical Characteristics (continued)

At $V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{open}$, $V_{OD} = 0\text{ V}$, $C_{PD} = 1\text{ pF}$, $\overline{EN} = 0\text{ V}$ (enabled), $\overline{IDC_EN} = 3.3\text{ V}$ (disabled), $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$ (unless otherwise noted)

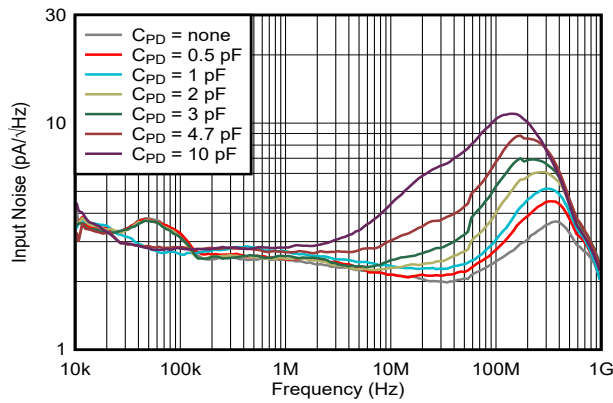


图 6-7. Input Noise Density vs Input Capacitance

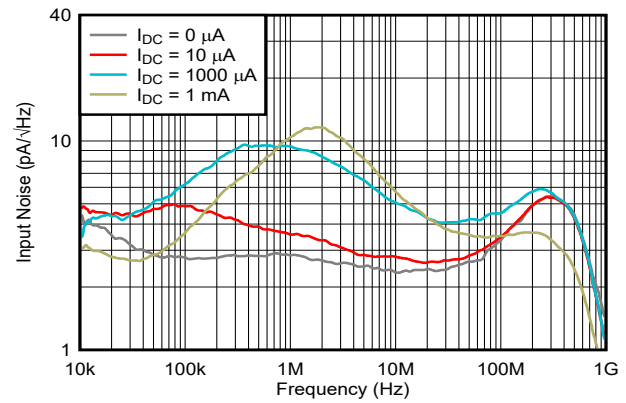


图 6-8. Input Noise Density vs Ambient Light DC Current

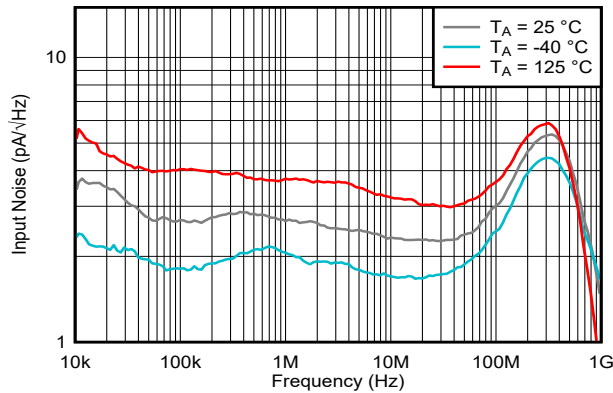


图 6-9. Input Noise Density vs Ambient Temperature

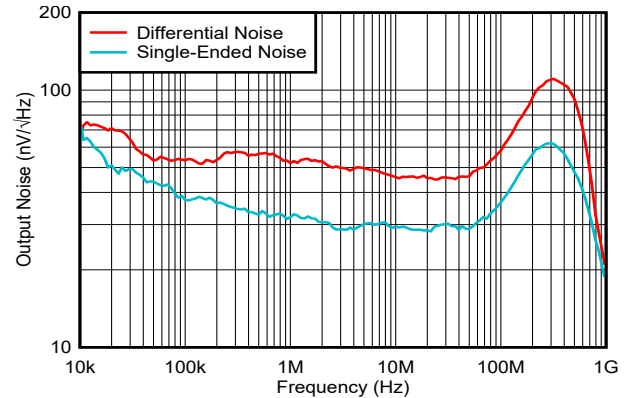


图 6-10. Output Noise Density vs Output Configuration

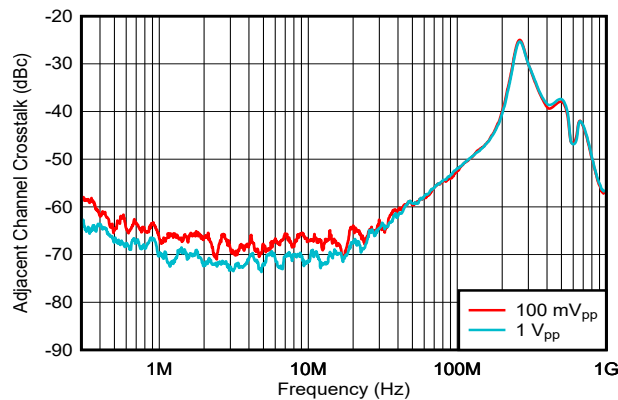


图 6-11. Adjacent Channel Crosstalk

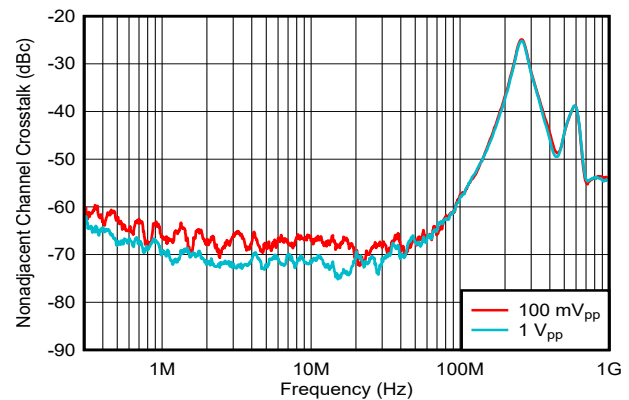


图 6-12. Non-Adjacent Channel Crosstalk

6.7 Typical Characteristics (continued)

At $V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{open}$, $V_{OD} = 0\text{ V}$, $C_{PD} = 1\text{ pF}$, $\overline{\text{EN}} = 0\text{ V}$ (enabled), $\overline{\text{IDC_EN}} = 3.3\text{ V}$ (disabled), $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$ (unless otherwise noted)

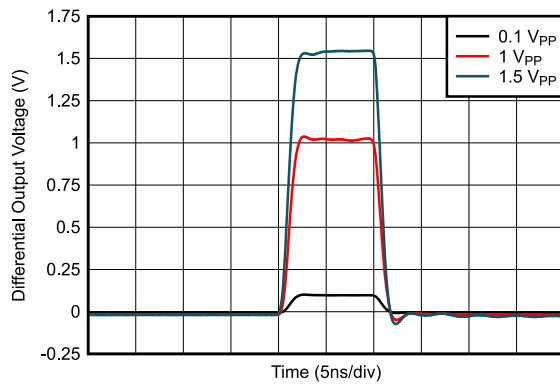


图 6-13. Pulse Response vs Output Swing

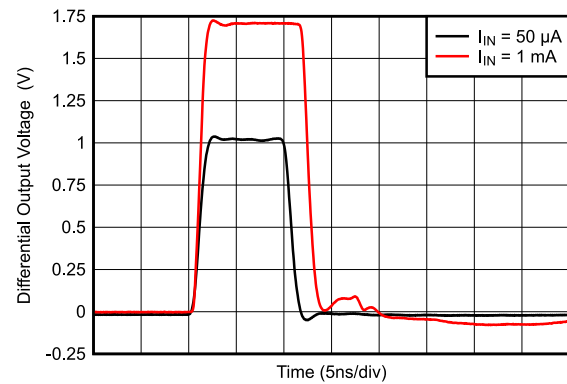


图 6-14. Overloaded Pulse Response

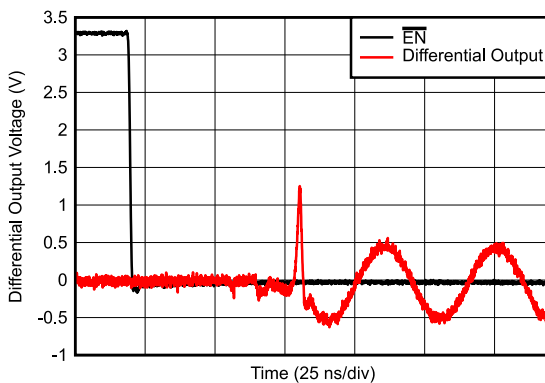


图 6-15. Turn-On Time

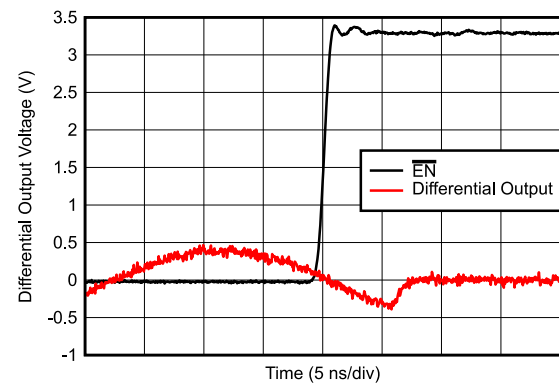
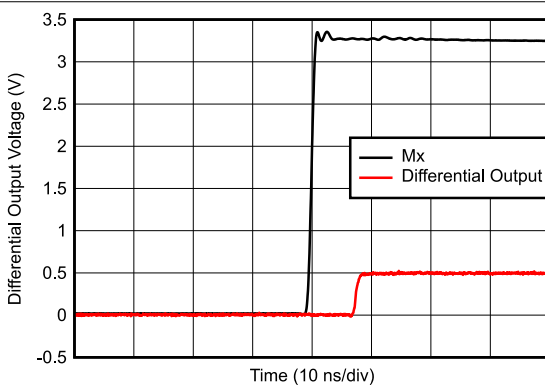


图 6-16. Turn-Off Time



0 → 0.5V transition at V_{OUT} (1% settling)

图 6-17. Channel Turn-On Response

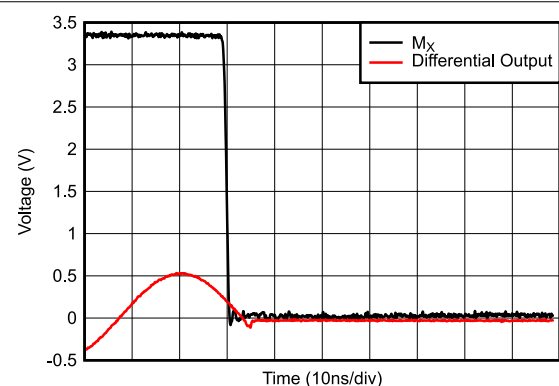


图 6-18. Channel Turn-Off Response

6.7 Typical Characteristics (continued)

At $V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{open}$, $V_{OD} = 0\text{ V}$, $C_{PD} = 1\text{ pF}$, $\overline{\text{EN}} = 0\text{ V}$ (enabled), $\overline{\text{IDC_EN}} = 3.3\text{ V}$ (disabled), $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$ (unless otherwise noted)

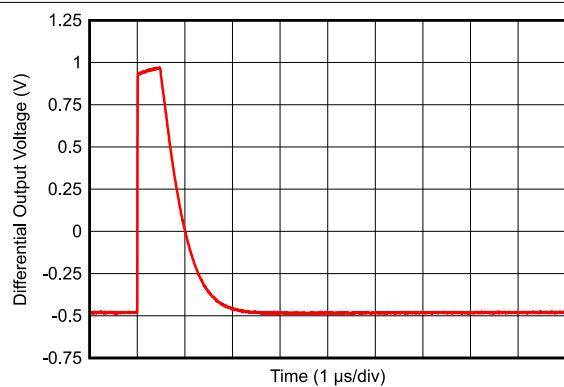


图 6-19. Ambient Loop Cancellation Settling Time ⁽¹⁾

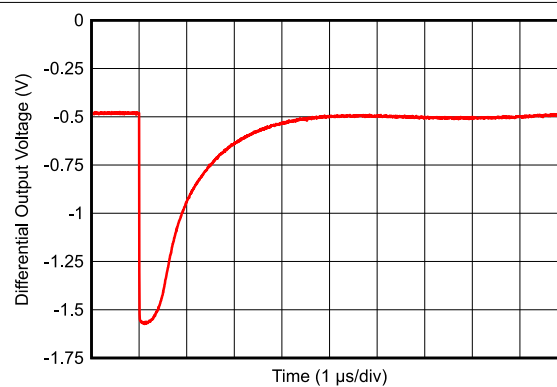


图 6-20. Ambient Loop Cancellation Settling Time ⁽¹⁾

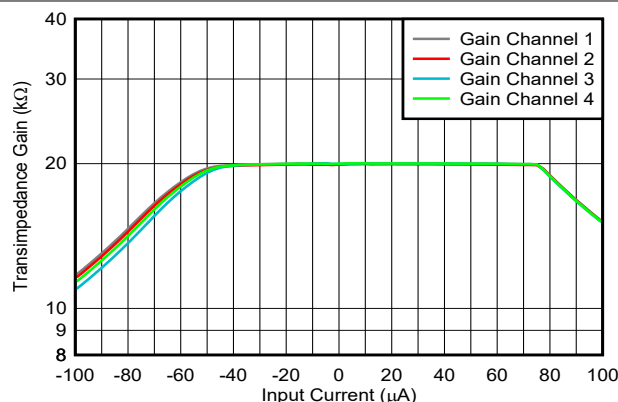


图 6-21. Transimpedance Gain vs Input Current

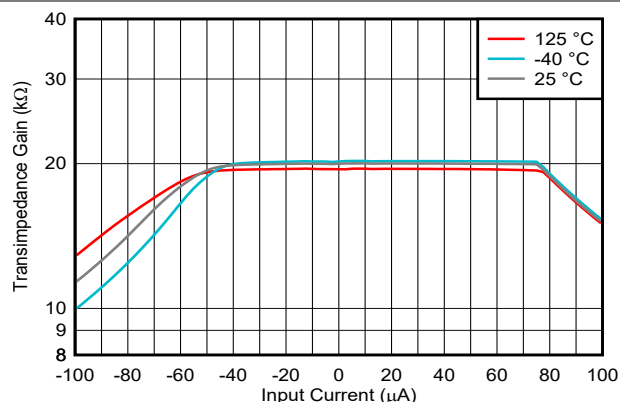


图 6-22. Transimpedance Gain vs Ambient Temperature

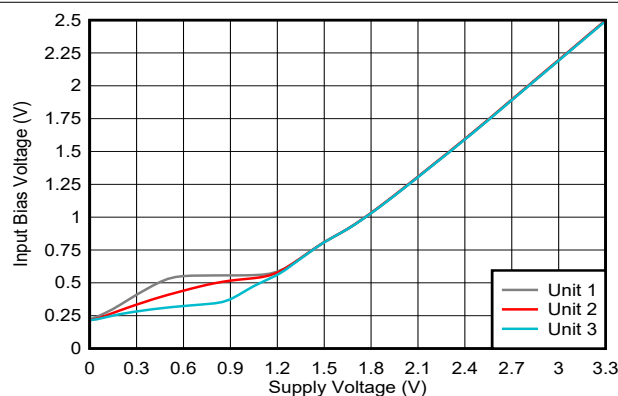


图 6-23. Input Bias Voltage vs Supply Voltage ⁽²⁾

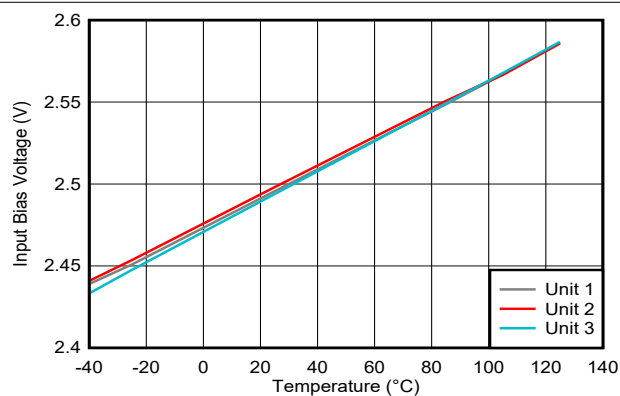


图 6-24. Input Bias Voltage vs Ambient Temperature ⁽²⁾

¹ Differential Output Voltage = (Vout+ - Vout-).

² Typical units from different lots.

6.7 Typical Characteristics (continued)

At $V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{open}$, $V_{OD} = 0\text{ V}$, $C_{PD} = 1\text{ pF}$, $\overline{\text{EN}} = 0\text{ V}$ (enabled), $\overline{\text{IDC_EN}} = 3.3\text{ V}$ (disabled), $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$ (unless otherwise noted)

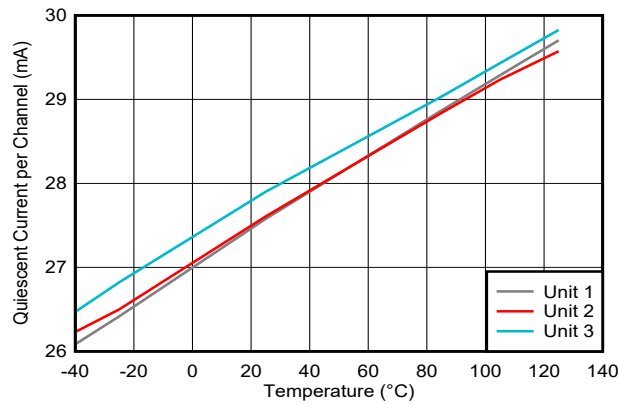


图 6-25. Quiescent Current (Per Channel) vs Ambient Temperature ⁽²⁾

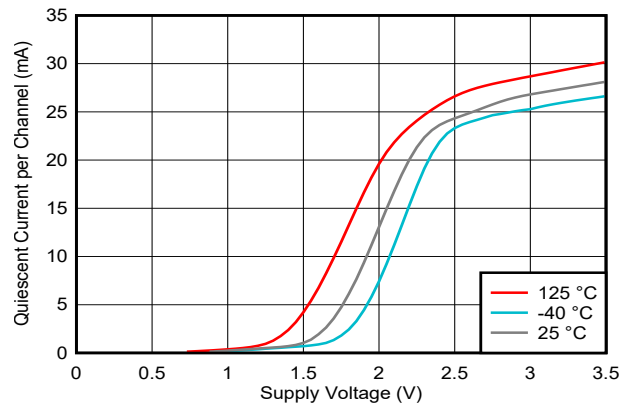
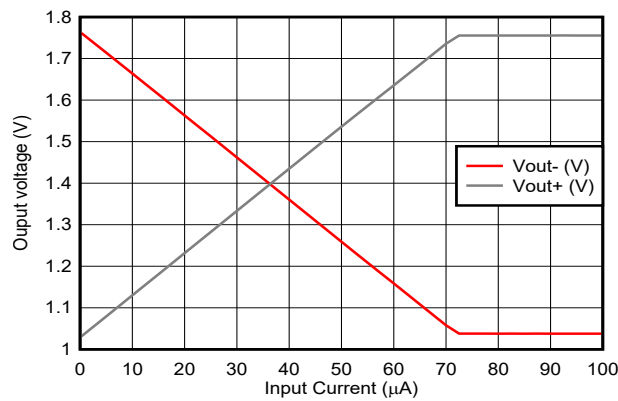
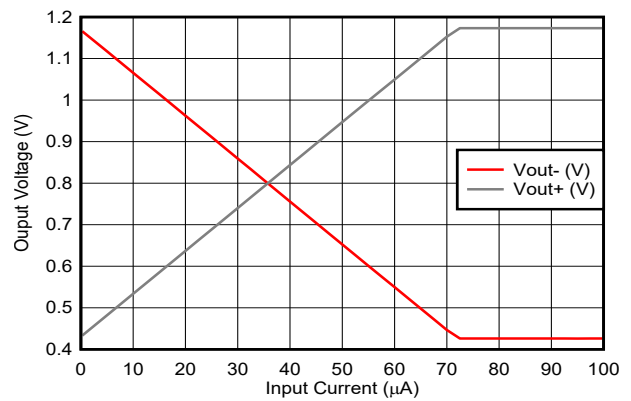


图 6-26. Quiescent Current (Per Channel) vs Supply Voltage



$V_{OD} = 0.75\text{ V}$, $V_{OCM} = 1.4\text{ V}$

图 6-27. High-Side Swing vs Input Current



$V_{OD} = 0.75\text{ V}$, $V_{OCM} = 0.8\text{ V}$

图 6-28. Low-Side Swing vs Input Current

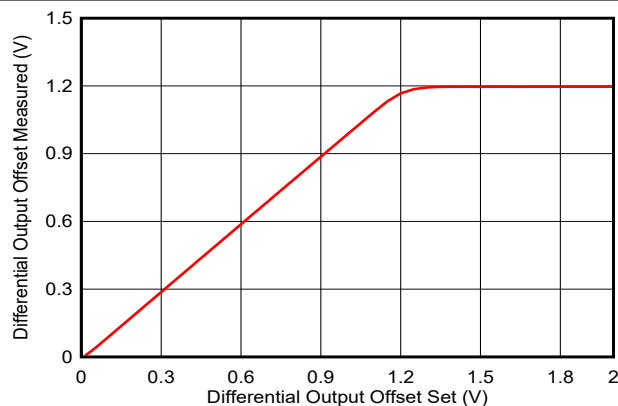
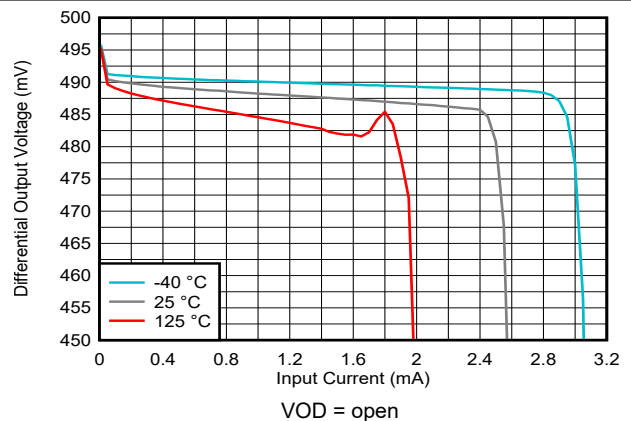


图 6-29. Differential Output Offset Gain



$V_{OD} = \text{open}$

图 6-30. Ambient Light Cancellation Range vs Ambient Temperature

6.7 Typical Characteristics (continued)

At $V_{DD} = 3.3\text{ V}$, $V_{OCM} = \text{open}$, $V_{OD} = 0\text{ V}$, $C_{PD} = 1\text{ pF}$, $\overline{\text{EN}} = 0\text{ V}$ (enabled), $\overline{\text{IDC_EN}} = 3.3\text{ V}$ (disabled), $R_L = 100\ \Omega$ (differential load between OUT+ and OUT-), and $T_A = 25^\circ\text{C}$ (unless otherwise noted)

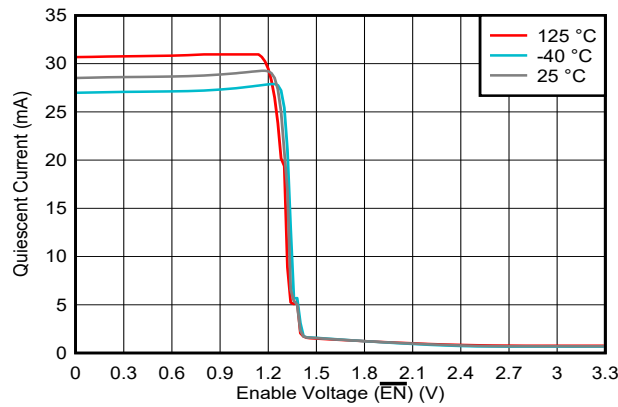


图 6-31. Logic Threshold vs Ambient Temperature

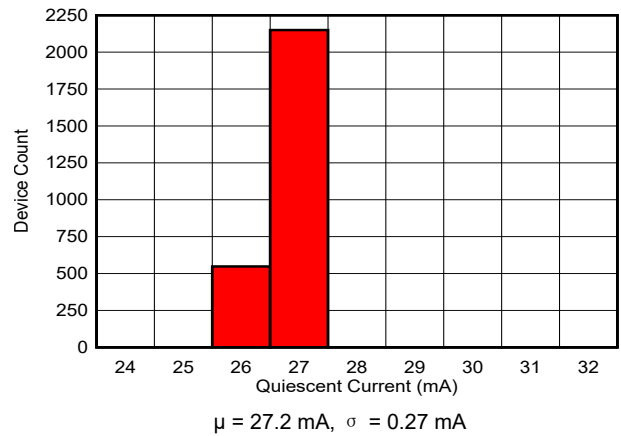


图 6-32. Quiescent Current Distribution

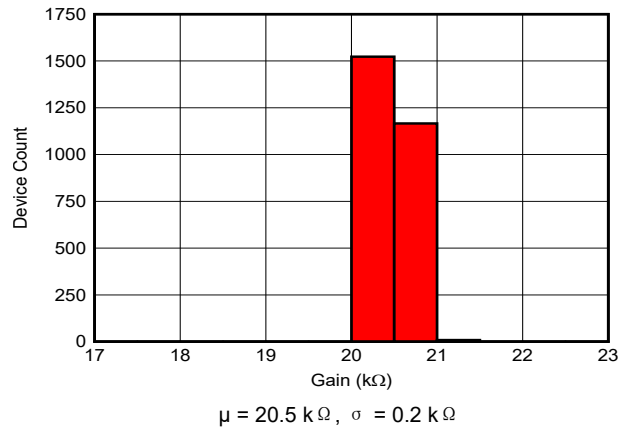


图 6-33. Transimpedance Gain Distribution

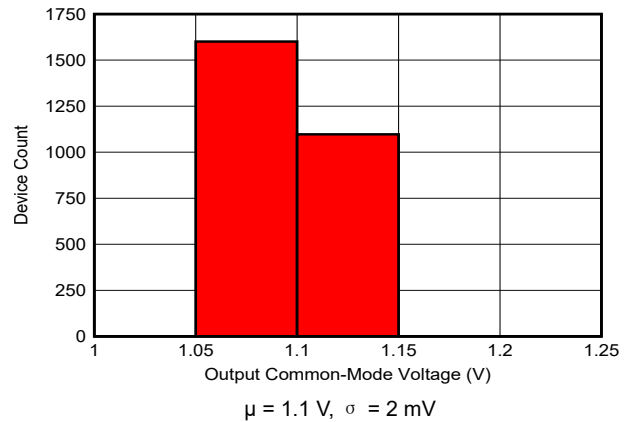


图 6-34. Output Common-Mode Voltage (V_{OCM}) Distribution

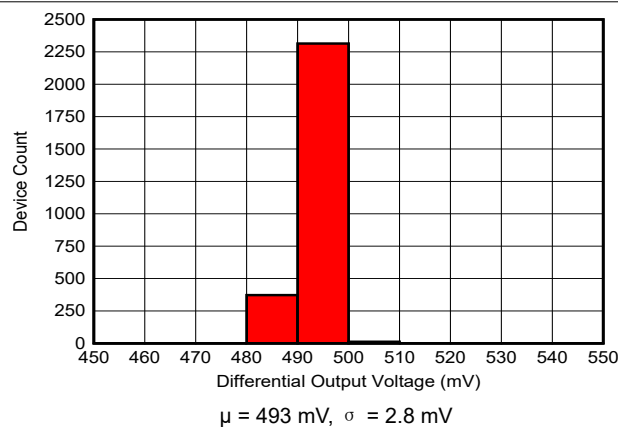


图 6-35. Differential Output Offset Voltage (V_{OD}) Distribution

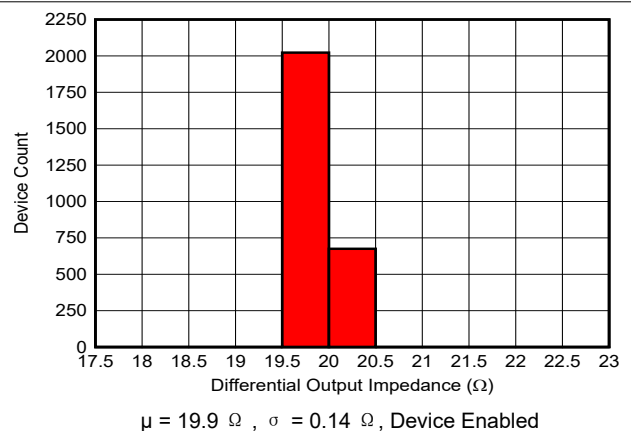


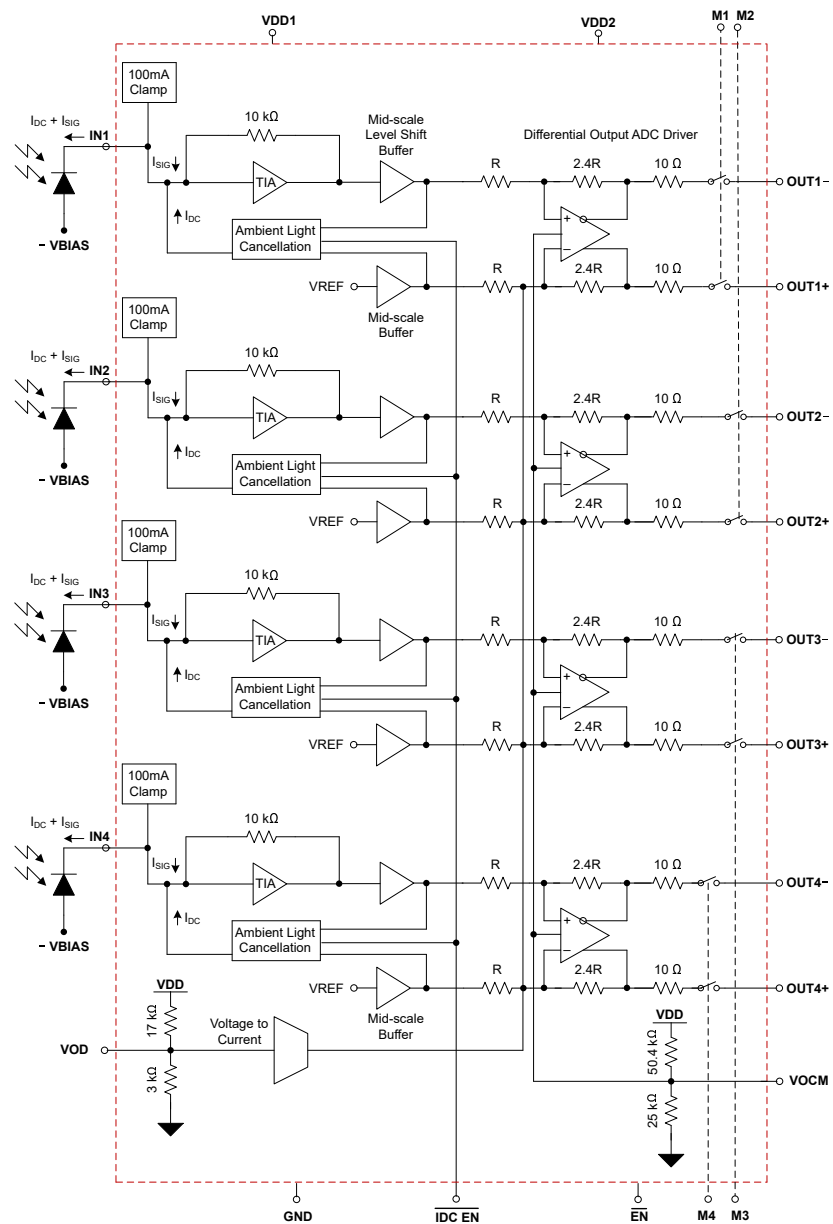
图 6-36. Differential Output Impedance (Z_{OUT}) Distribution

7 Detailed Description

7.1 Overview

The LMH32404 is a quad-channel, differential output, high-speed transimpedance amplifier (TIA) geared towards light detection and ranging (LIDAR) and laser distance measurement systems. Each LMH32404 channel has integrated switches on the output to disconnect the differential output amplifier from the output pins. This enables the LMH32404 to be highly configurable in a multi-channel LIDAR system. The LMH32404 device is designed to work with photodiodes (PDs), for example avalanche photodiodes (APDs), connected in configurations that can source or sink the current. When the photodiode sinks the photocurrent (anode is biased to a negative voltage and cathode is tied to the amplifier input) the fast recovery clamp activates when the amplifier input is overloaded. When the photodiode sources the photocurrent (cathode is biased to a positive voltage and anode is tied to the amplifier input) a soft clamp activates when the amplifier input is overloaded. When the soft clamp activates the amplifier takes longer to recover. The recovery time depends on the level of input overload. The LMH32404 is offered in a space-saving 5-mm × 4-mm, 28-pin VQFN package and is rated over a temperature range from –40°C to +125°C.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Clamping and Input Protection

The LMH32404 device is optimized to work with photodiodes (PD) configurations that can source or sink current; however, the LMH32404 is optimized for a sinking current configuration. It is assumed that the LMH32404 device is being used with a PD that is configured with its cathode tied to the amplifier input and the anode tied to a negative supply voltage, unless stated otherwise.

The LMH32404 features two internal clamps, a fast recovery clamp and a soft clamp. The fast recovery clamp is the active clamp when the photodiode is sinking a photocurrent. The soft clamp is the active clamp when the photodiode is sourcing a photocurrent. Stray reflections from nearby objects with high reflectivity can produce large output current pulses from the PD. The linear input range of the LMH32404 is approximately 65 μ A. Input currents in excess of the linear current range will cause the internal nodes of the amplifier to saturate, which increases the amplifier recovery time. The end result broadens the output pulse, which leads to blind zones.

To protect against this condition, the LMH32404 features an integrated fast recovery clamp that absorbs and diverts the excess current to the positive supply (V_{DD1}) when the amplifier detects its nodes entering a saturated condition. The integrated clamp minimizes the pulse extension to less than a few nanoseconds for input pulses up to 100 mA. The power-supply pins (V_{DD1} and V_{DD2}) must have their own bypass capacitors to prevent large input pulses from affecting the differential output stage. The clamp circuitry is active when the amplifier is in standby mode and low-power mode, thereby protecting the TIA input.

7.3.2 ESD Protection

All LMH32404 IO pins (excluding V_{DD1} , V_{DD2} , and GND) have an internal electrostatic discharge (ESD) protection diode to the positive and negative supply rails to protect the amplifier from ESD events.

7.3.3 Differential Output Stage

Each channel of the LMH32404 has a differential output stage that performs two functions that are common across all differential amplifiers. This stage does the following:

1. Converts the single-ended output from the TIA stage to a differential output.
2. Performs a common-mode output shift to match the specified ADC input common-mode voltage.

The VOD pin is functional only when the LMH32404 device is used with a PD that sinks the photocurrent. Set $V_{OD} = 0$ V when the LMH32404 device is interfaced with a PD that sources the photocurrent. The differential output stage has two 10- Ω series resistors on its output to isolate the amplifier output stage transistors from the package bond-wire inductance and printed circuit board (PCB) capacitance. The net gain of the LMH32404 (TIA plus the output stage) is 20 k Ω per channel when driving an external 100- Ω resistor. When the external load resistor is increased above 100 Ω , the effective gain from the IN pin to the differential output pin increases. Consequently, when the external load resistor is decreased to less than 100 Ω , the effective gain from the IN pin to the differential output pin decreases as a result of the larger voltage drop across the two internal 10- Ω resistors. The effective TIA gain is 24 k Ω when there is no load resistor between the OUT+ and OUT – pins.

The output common-mode voltage of the LMH32404 can be set externally through the VOCM pin. A resistor divider internal to the amplifier, between V_{DD2} and ground sets the default voltage to 1.1 V. The internal resistors generate common-mode noise that is typically rejected by the CMRR of the subsequent ADC stage. To maximize the amplifier SNR, place an external noise bypass capacitor to ground on the VOCM pin. In single-ended signal chains, such as ToF systems that use time-to-digital converters (TDCs), only a single output per channel of the LMH32404 is needed. In such situations, terminate the unused differential output in the same manner as the used output to maintain balance and symmetry. The signal swing of the single-ended output is half the available differential output swing. Additionally, the common-mode noise of the output stage, which is typically rejected by the differential input ADC, is now added to the total noise, further degrading SNR.

The output stage of the LMH32404 has an additional VOD input that sets the differential output between OUT⁻ and OUT⁺. 图 7-1 shows how each output pin of the LMH32404 is at the voltage set by the V_{OCM} pin (default = 1.1 V) when the photodiode output current is zero and the VOD input is set to 0 V. When the VOD pin is driven to a voltage of X volts, the two output pins are separated by X volts when the photodiode current is zero. The average voltage is still equal to V_{OCM}. For example, 图 7-2 shows how if V_{OCM} is set to 1.1 V and VOD is set to 0.4 V, then OUT⁻ = 1.1 V + 0.2 V = 1.3 V and OUT⁺ = 1.1 V - 0.2 V = 0.9 V.

The VOD output offset feature is included in the LMH32404 because the output current of a photodiode is unipolar. Depending on the reverse bias configuration, a photodiode can either sink or source current, but cannot do both at the same time. With the anode connected to a negative bias and the cathode connected to the TIA stage input, the photodiode can only sink current, which implies that the TIA stage output swings in a positive direction above its default input bias voltage. Subsequently, OUT⁻ only swings below V_{OCM} and OUT⁺ only swings above V_{OCM}. 图 7-1 shows how the with VOD = 0 V, the LMH32404 only uses half its output swing range ($V_{OUT} = V_{OUT+} - V_{OUT-}$), because one output never swings below V_{OCM} and the other output never goes above V_{OCM}. The signal dynamic range in this case is $0.4 V_{PP} - 0 V = 0.4 V_{PP}$.

图 7-2 shows how the VOD pin voltage allows OUT⁻ to be level-shifted above V_{OCM}, and OUT⁺ to be level-shifted below V_{OCM} to maximize the output swing capabilities of the amplifier. The signal dynamic range in this case is $0.4 V_{PP} - (-0.4 V_{PP}) = 0.8 V_{PP}$.

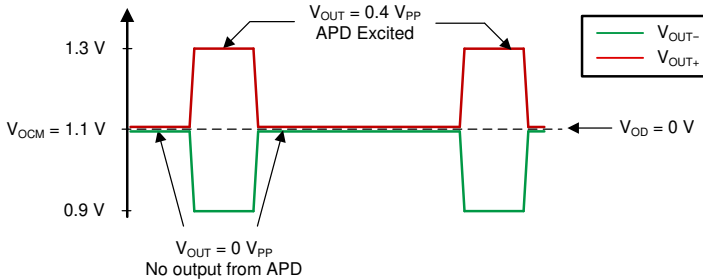


图 7-1. Single-Ended Outputs With VOD = 0 V

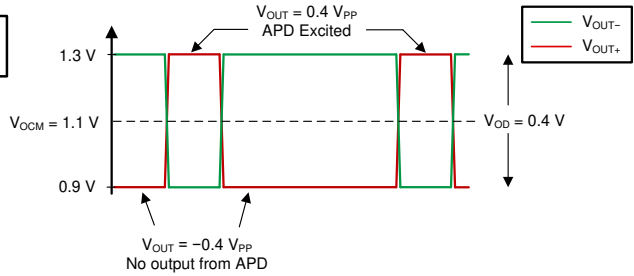


图 7-2. Single-Ended Outputs With VOD = 0.4 V

When the LMH32404 drives a 100-Ω load, the voltage set at the VOD pin is equal to the differential output offset ($V_{OUT} = V_{OUT+} - V_{OUT-}$) when the input signal current is zero. Use 方程式 1 to calculate the differential output offset under other load conditions.

$$V_{OD} = 1.2 \times VOD \times \frac{R_L}{(R_L + 20 \Omega)} \quad (1)$$

where

- VOD = Voltage applied at pin 10
- V_{OD} = ($V_{OUT-} - V_{OUT+}$)
- R_L = External load resistance

7.4 Device Functional Modes

7.4.1 Ambient Light Cancellation (ALC) Mode

The LMH32404 has an integrated DC cancellation loop that cancels and voltage offsets from incidental ambient light. The ALC mode only works when the PD is sinking the photocurrent. The DC cancellation loop is enabled by setting $\overline{\text{IDC_EN}}$ low. Incident ambient light on a photodiode produces a DC current resulting in an offset voltage at the output of the TIA stage.

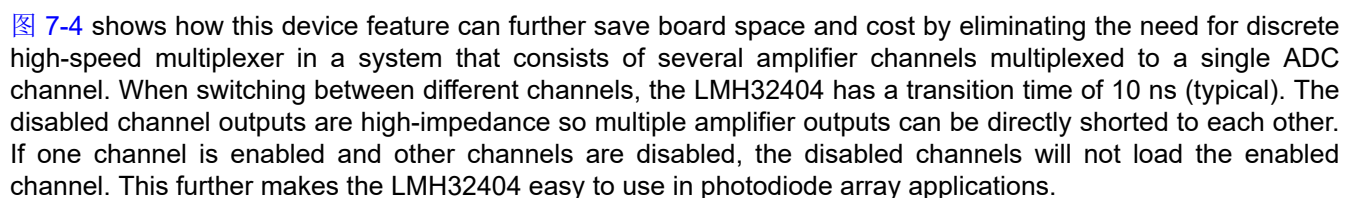
If the photodiode produces a DC output current resulting from ambient light, the output of the level-shift buffer stage is offset from the reference voltage V_{REF} . The ALC loop detects this offset and produces an opposing DC current to compensate for the differential offset voltage at its input. The loop has a high-pass cutoff frequency of 400 kHz. The ambient light cancellation loop is disabled when the amplifier is placed in low-power mode.

The shot noise current introduced by the DC cancellation loop increases the overall amplifier noise; so, if the ambient light level is negligible, then disable the loop to improve SNR. The cancellation loop helps save PCB space and system costs by eliminating the need for external AC coupling passive components. Additionally, the extra trace inductance and PCB capacitance introduced by using external AC coupling components degrades the LMH32404 dynamic performance.

The ambient light cancellation loop is active (depending on $\overline{\text{IDC_EN}}$ configuration) when one or more of the channels is in standby mode. The ambient light cancellation loop is disabled when the amplifier is placed in low-power mode. When the LMH32404 is brought out of low-power operation the ambient light cancellation loop requires several time constants to settle. The time constant is based on the 400-kHz cutoff frequency of the loop. When in standby mode, the ALC loop is still active depending on $\overline{\text{IDC_EN}}$ configuration.

7.4.2 Channel Multiplexer Mode

The LMH32404 is a highly integrated transimpedance amplifier device with four independent channels. Each channel has its own single-ended input, differential output stage and multiplexing switch. The integrated switch can be used to disconnect the differential output amplifier from the output pin, thereby enabling high-impedance output for the respective channel.

 **Figure 7-4** shows how this device feature can further save board space and cost by eliminating the need for discrete high-speed multiplexer in a system that consists of several amplifier channels multiplexed to a single ADC channel. When switching between different channels, the LMH32404 has a transition time of 10 ns (typical). The disabled channel outputs are high-impedance so multiple amplifier outputs can be directly shorted to each other. If one channel is enabled and other channels are disabled, the disabled channels will not load the enabled channel. This further makes the LMH32404 easy to use in photodiode array applications.

Set M_x (M_1 , M_2 , M_3 , or M_4) high for the corresponding channel to be enabled and output switches closed. Set M_x to logic low (default state) for the corresponding channel to be disabled (standby mode) and output switches open. When the channel is in its standby power mode, the clamp circuitry is still active thereby protecting the TIA input. Also, when in standby mode, the ALC loop is still active depending on $\overline{\text{IDC_EN}}$ configuration.

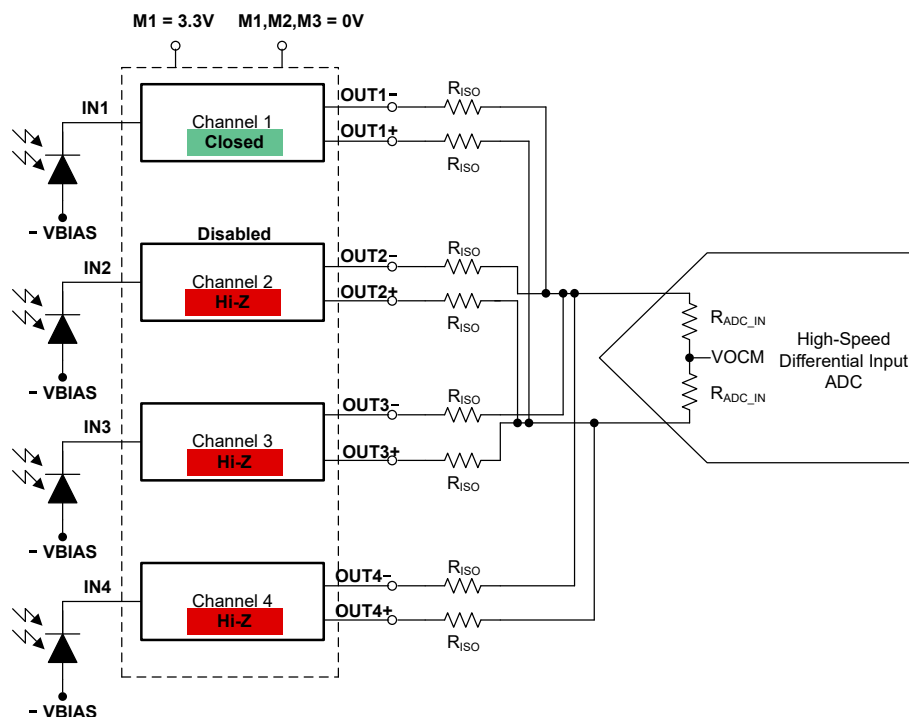


图 7-3. Configuring LMH32404 in Channel Multiplexer Mode to Drive a Single ADC

7.4.3 Low-Power Mode

The LMH32404 can be placed in low-power mode by setting $\overline{\text{EN}}$ high, which helps in saving system power. Enabling low-power mode puts the outputs of the internal amplifiers in the LMH32404, including the differential outputs, in a high-impedance state.

If a system consists of high number of amplifier channels multiplexed to a few ADC channels. 图 7-4 shows how this device feature can further save board space and cost by eliminating the need for a discrete high-speed multiplexer. The disabled LMH32404 outputs are high-impedance so multiple LMH32404 device outputs can be directly shorted to each other. If one LMH32404 device is enabled and others are disabled, the disabled devices will not load the enabled device. This further makes the LMH32404 easy to use in photodiode array applications.

When the amplifier is in its low-power mode, the clamp circuitry is still active thereby protecting the TIA input. The ambient light cancellation loop is disabled when the amplifier is placed in low-power mode. When the LMH32404 is brought out of low-power operation the ambient light cancellation loop requires several time constants to settle. The time constant is based on the 400-kHz cutoff frequency of the loop.

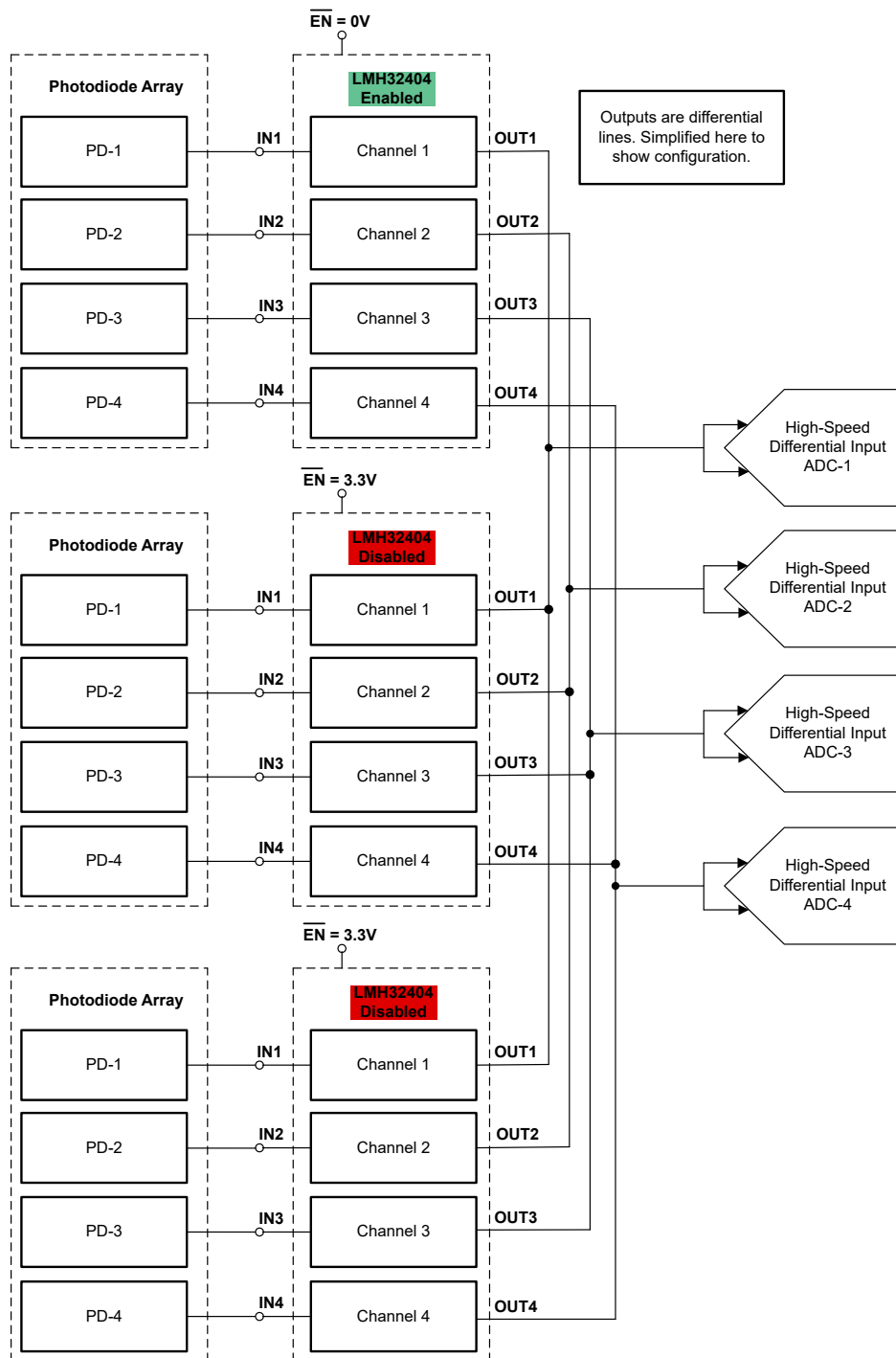


图 7-4. Configuring Three LMH32404 Devices to Drive Four ADC Channels

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

Each differential output pair of the LMH32404 can directly drive a high-speed differential input ADC. 图 8-1 shows how the effective signal the effective signal gain between the TIA input and the ADC input is $20\text{ k}\Omega$ when driving an ADC with a $100\text{-}\Omega$ differential input impedance ($R_{\text{ADC_IN}} = 50\text{ }\Omega$). 方程式 2 gives the effective signal gain between the TIA input and the ADC input when driving an ADC with any other value of differential input impedance ($R_{\text{ADC_IN}} \neq 50\text{ }\Omega$).

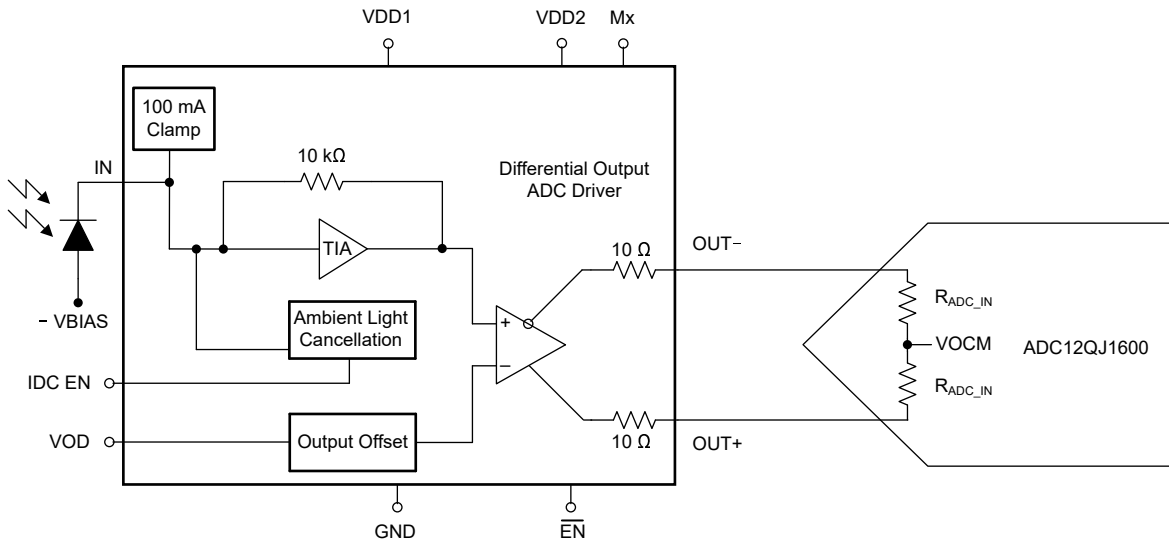


图 8-1. LMH32404 (Single Channel) to ADC Interface

$$A_v = 20\text{ k}\Omega \times 1.2 \times \frac{2 \times R_{\text{ADC_IN}}}{(2 \times R_{\text{ADC_IN}} + 20\text{ }\Omega)} \quad (2)$$

where

- A_v = Differential gain from the TIA input to the ADC input
- $R_{\text{ADC_IN}}$ = Input resistance of the ADC

图 8-2 shows that in some designs a matching resistor network can be inserted between the LMH32404 output and the ADC inputs. 方程式 3 gives the effective gain from the TIA input to the ADC input when using a matching resistor network.

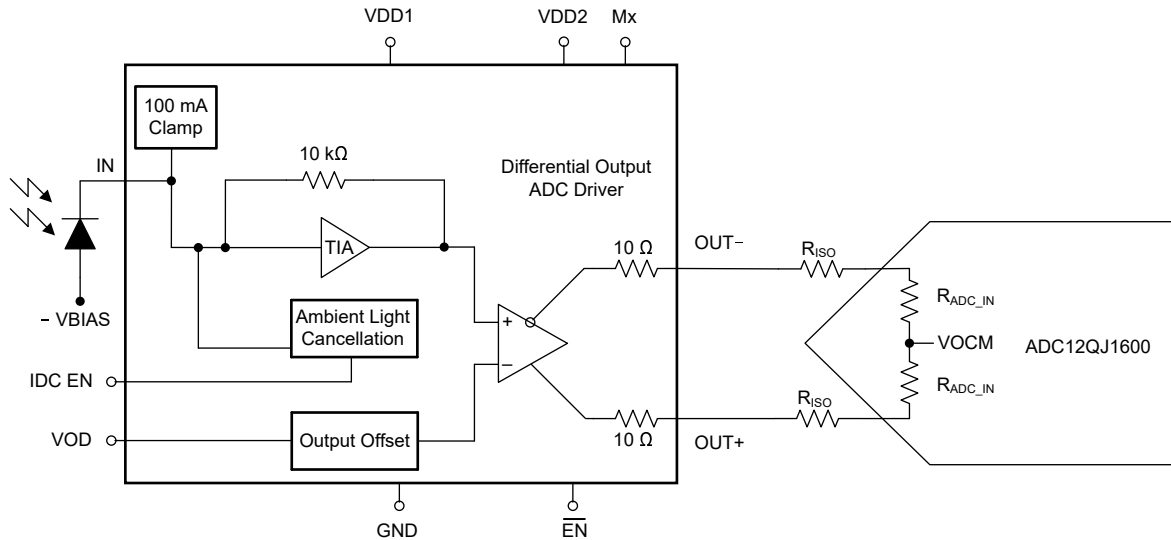


图 8-2. LMH32404 (Single Channel) to ADC Interface With a Matching Resistor Network

$$A_V = 20 \text{ k}\Omega \times 1.2 \times \frac{2 \times R_{\text{ADC_IN}}}{(2 \times R_{\text{ADC_IN}} + 2 \times R_{\text{ISO}} + 20 \Omega)} \quad (3)$$

where

- A_V = Gain from the TIA input to the ADC input
- $R_{\text{ADC_IN}}$ = Differential input resistance of the ADC
- R_{ISO} = Series resistance between the TIA and ADC

方程式 4 gives the voltage to be applied at the VOD pin (pin 10) if a certain differential offset voltage (V_{OD}) is needed at the ADC input for the circuit in 图 8-2.

$$V_{\text{OD}} = V_{\text{OD}} \times \left(\frac{1}{1.2} \right) \times \frac{(2 \times R_{\text{ADC_IN}} + 2 \times R_{\text{ISO}} + 20 \Omega)}{(2 \times R_{\text{ADC_IN}})} \quad (4)$$

where

- V_{OD} = Voltage applied at pin 10
- V_{OD} = Desired differential offset voltage at the ADC input
- $R_{\text{ADC_IN}}$ = Differential input resistance of the ADC
- R_{ISO} = Series resistance between the TIA and ADC

8.2 Typical Application

8.2.1 Standard TIA Application

图 8-3 and 图 8-4 shows the circuit used to test the LMH32404 with a voltage source.

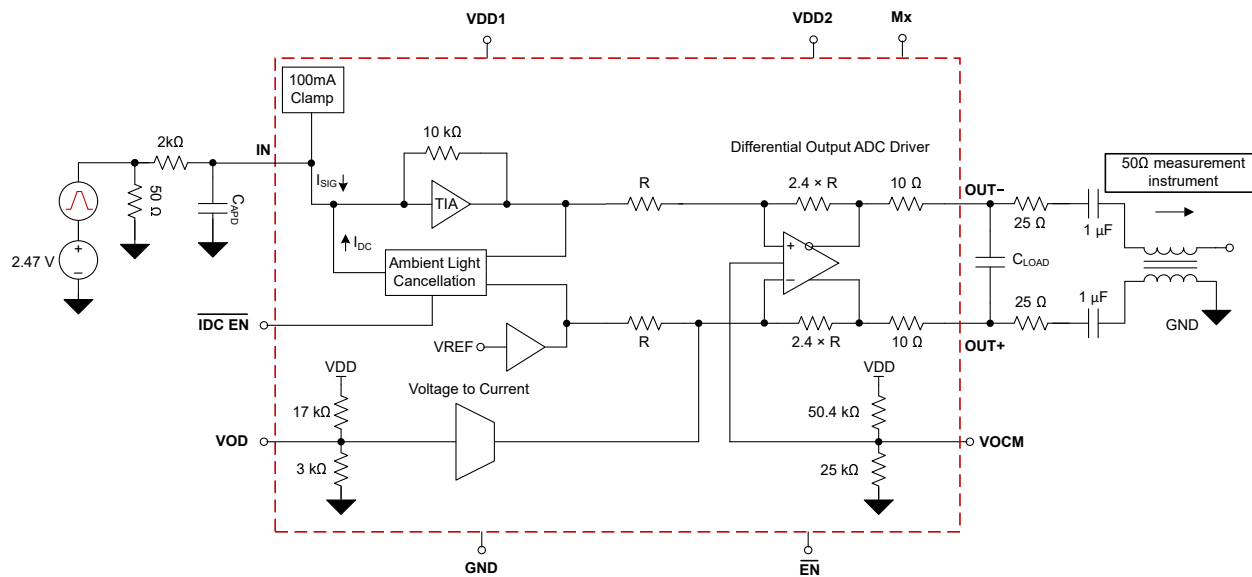


图 8-3. LMH32404 Single Channel Test Circuit for Single-Ended Measurement

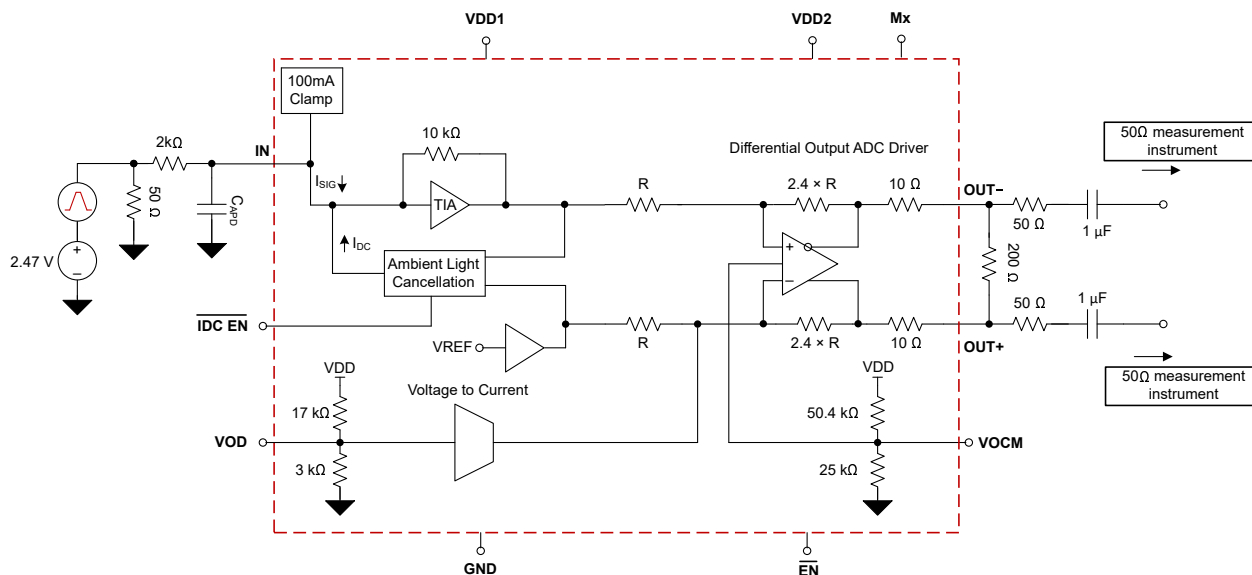


图 8-4. LMH32404 Single Channel Test Circuit for Differential Measurement

8.2.1.1 Design Requirements

The objective is to design a low-noise, wideband differential output transimpedance amplifier. The design requirements are:

- Amplifier supply voltage: 3.3 V
- Transimpedance gain: 20 k Ω
- Photodiode capacitance: C_{APD} = 1 pF
- Target bandwidth: > 300 MHz
- Multiple channels for array applications

8.2.1.2 Detailed Design Procedure

图 8-3 和 图 8-4 展示了 LMH32404 测试电路，用于测量其带宽、噪声和瞬态响应。电压源是 DC 偏置，接近 LMH32404 的输入偏置电压。LMH32404 的内部设计优化为仅从输入引脚 (INx) sourcing 电流。当测试 LMH32404 时，使用网络分析仪或正弦波源，设置 DC 偏置，使得输入 AC 和 DC 分量的总和不会导致电流流入放大器输入。仅使用 LMH32404 与 avalanche 光电二极管 (APDs) 配合使用，它们会 sink 电流。阳极偏置 APD 满足此要求。

图 8-5 显示了 LMH32404 所有四个通道的带宽测量结果。

图 8-6 显示了 LMH32404 的输出噪声谱密度， $C_{APD} = 1$ pF，且无光电二极管电容。

图 8-7 显示了 LMH32404 通道的开启时间，当 Mx 引脚从逻辑低电平切换到高电平时。当放大器关闭时，输出处于高阻抗状态。当放大器开启时，输出会 settling 并开始跟踪输入，在几纳秒内。

图 8-8 显示了 LMH32404 通道的关闭时间，当 Mx 引脚从逻辑高电平切换到低电平时。当放大器关闭时，输出处于高阻抗状态。

8.2.1.3 Application Curves

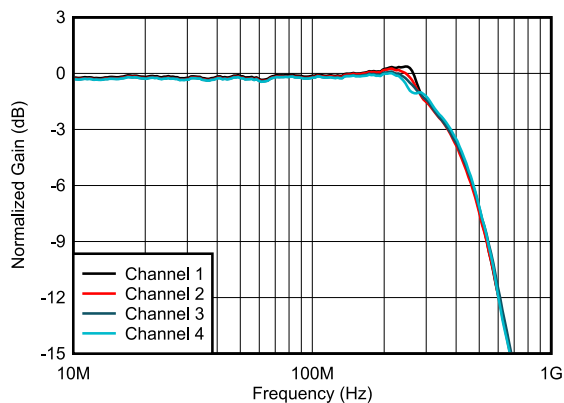


图 8-5. Transimpedance Bandwidth

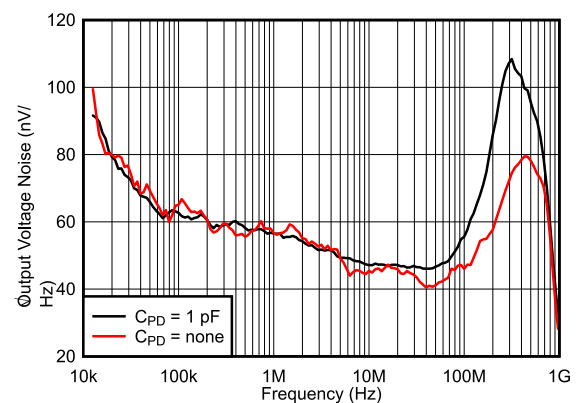


图 8-6. Output Noise Spectral Density

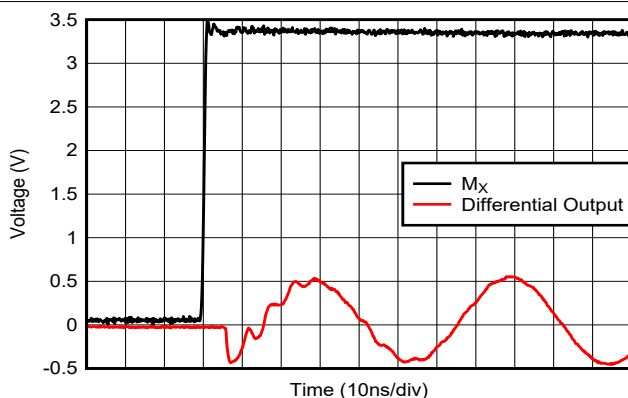


图 8-7. Channel Turn-On Response

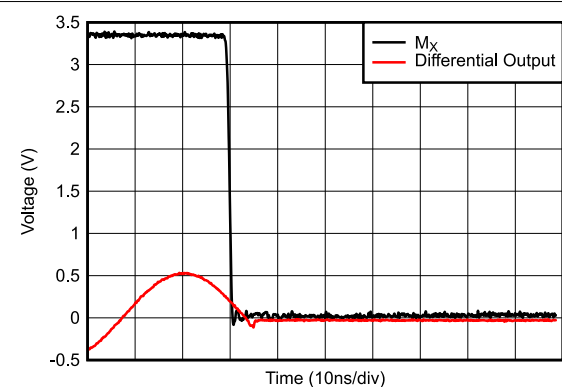


图 8-8. Channel Turn-Off Response

8.2.2 Increase Channel Density for Optical Front-End Systems

Modern LiDAR systems are moving towards solid state configurations with multi-channel photodiode arrays. For optical front-end designs it is impractical to have single transimpedance amplifiers (TIA) connected to each diode output along with additional multiplexers or other switching solutions to connect to the digitizer. This approach causes increased solution size, complexity and signal degradation.

The LMH32404 resolves this problem in two ways, by providing higher integration within the device and by allowing user configured output multiplexing for independent output control.

图 8-9 shows a comparison of a non-integrated front end using individual amplifiers, a multiplexer, and fully-differential amplifier (FDA) to connect to the differential input ADC. In comparison, the front end using the LMH32404 is able to connect four channels per amplifier to each ADC or set of ADC differential inputs. 图 8-9 shows how the LMH32404 improves solution size and system complexity compared to a non-integrated solution. With the additional features like input current clamps and ambient light cancellation, LMH32404 also improves system design and eliminates need for additional circuitry.

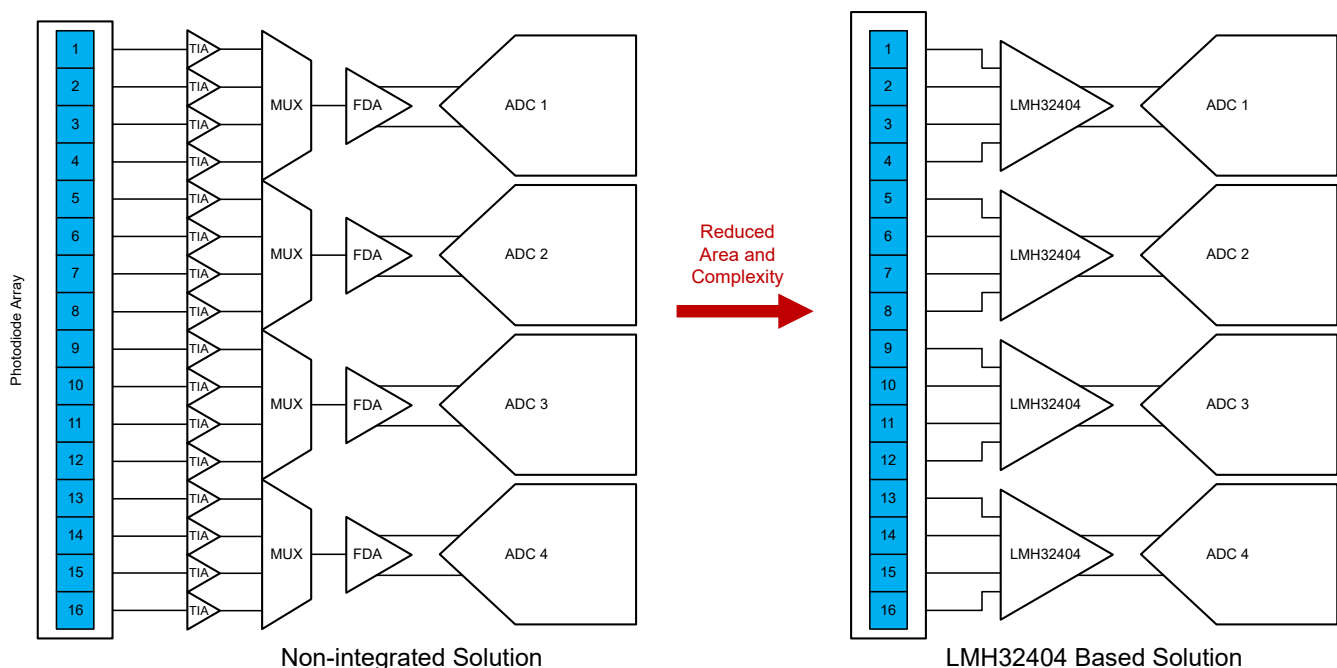


图 8-9. Solution Size Comparison

LMH32404 is a quad-channel device and each channel has an independent differential output stage and multiplexing switch. 图 8-10 shows two common output configurations. In a four-to-four configuration the LMH32404 operates with no output multiplexing with each input and corresponding differential output active. This configuration is useful when the user needs to be able to capture data from four optical sensors simultaneously. In a four-to-one configuration, the LMH32404 internally multiplexes all four differential outputs into a single differential output. The LMH32404 outputs can be configured in any permutation such as one channel operating in one-to-one mode with the other three channels multiplexed in a three-to-one configuration. This independent control and multiplexing feature significantly increases channel density for systems that do not need to record all inputs simultaneously.

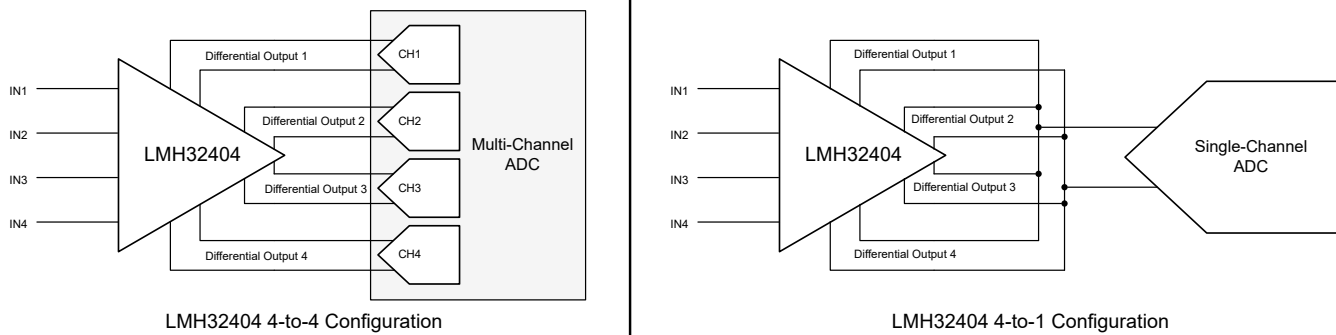


图 8-10. LMH32404 Multiplexing Configuration Examples

To show the front-end design integration and multiplexing capability, the LMH32404 performance was measured with the ADC12QJ1600-Q1 quad channel analog to digital converter. 图 8-11 shows the data measured from the ADC12QJ1600-Q1 using a 10 ns electrical input pulse on a single channel of the LMH32404. These pulses are similar to outputs seen in a typical LiDAR application. 图 8-12 shows the data from the ADC12QJ1600-Q1 when the LMH32404 outputs multiplex between different channels. The initial output shows a 10ns duration pulse train on channel 1, followed by a 20 MHz sinusoidal signal on channel 2 and then the output with all channels turned off but the input signals still present. Details on these measurements and application are discussed in the application brief, [How to Increase the Channel Density of LiDAR Systems with the 4-Channel LMH32404 Transimpedance Amplifier](#).

8.2.2.1 Application Curves

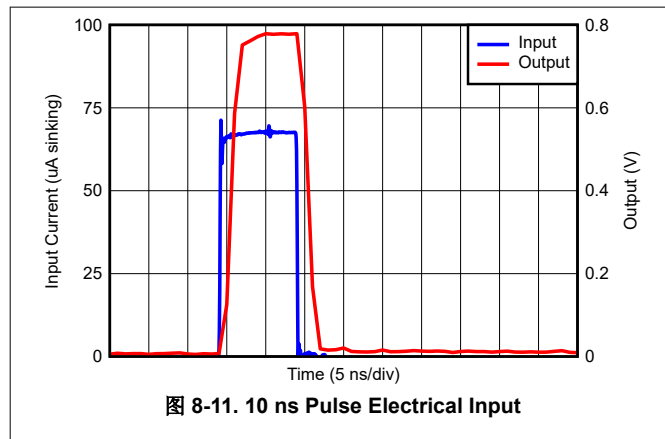


图 8-11. 10 ns Pulse Electrical Input

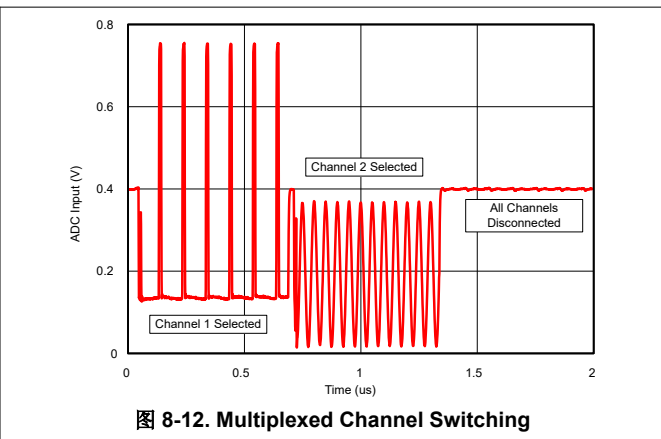


图 8-12. Multiplexed Channel Switching

9 Power Supply Recommendations

The LMH32404 operates on 3.3-V supplies. The VDD1 and VDD2 pins must always be driven from the same supply source and individually bypassed. Use multiple bypass capacitors in parallel, because a low power-supply source impedance must be maintained across frequency. Place the bypass capacitors as close to the supply pins as possible. Place the smallest capacitor on the same side of the PCB as the LMH32404. Placing the larger valued bypass capacitors on the same side of the PCB is preferable as well; if there are space constraints however, the capacitors can be moved to the opposite side of the PCB using multiple vias to reduce the series inductance resulting from the vias. The LMH32404 can be run on bipolar supplies by connecting pins 11 and 26 to the negative supply. The thermal pad must always be connected to the most negative supply. The digital pin threshold voltages must be appropriately level shifted as they are referred to voltages at pins 11 and 26.

10 Layout

10.1 Layout Guidelines

Achieving optimum performance with a high-frequency amplifier such as the LMH32404 requires careful attention to board layout parasitics and external component types. Recommendations that optimize performance include:

- **Minimize parasitic capacitance from the signal I/O pins to ac ground.** Parasitic capacitance on the output pins can cause instability, whereas parasitic capacitance on the input pin reduces the amplifier bandwidth. Cut out the power and ground traces under the signal input and output pins to reduce unwanted capacitance. Otherwise, ground and power planes must be unbroken elsewhere on the board.
- **Minimize the distance from the power-supply pins to high-frequency bypass capacitors.** Use low inductance ceramic capacitors as decoupling capacitors with voltage ratings at least three times greater than the amplifiers maximum power supplies. Place a combination of 100 pF (or higher) and 33 nF (or higher) capacitors on the same side as the DUT. If space constraints force the larger value bypass capacitors to be placed on the opposite side of the PCB, use multiple vias on the supply and ground side of the capacitors. This configuration makes sure that there is a low-impedance path to the amplifiers power-supply pins across the amplifiers gain bandwidth specification. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. Larger (2.2- μ F to 6.8- μ F) decoupling capacitors that are effective at lower frequency must be used on the supply pins. Place these decoupling capacitors further from the device. Share the decoupling capacitors among several devices in the same area of the printed circuit board (PCB).
- For more information on board design and layout, see the evaluation module user guide, [LMH32404 Evaluation Module User's Guide](#).

10.2 Layout Example

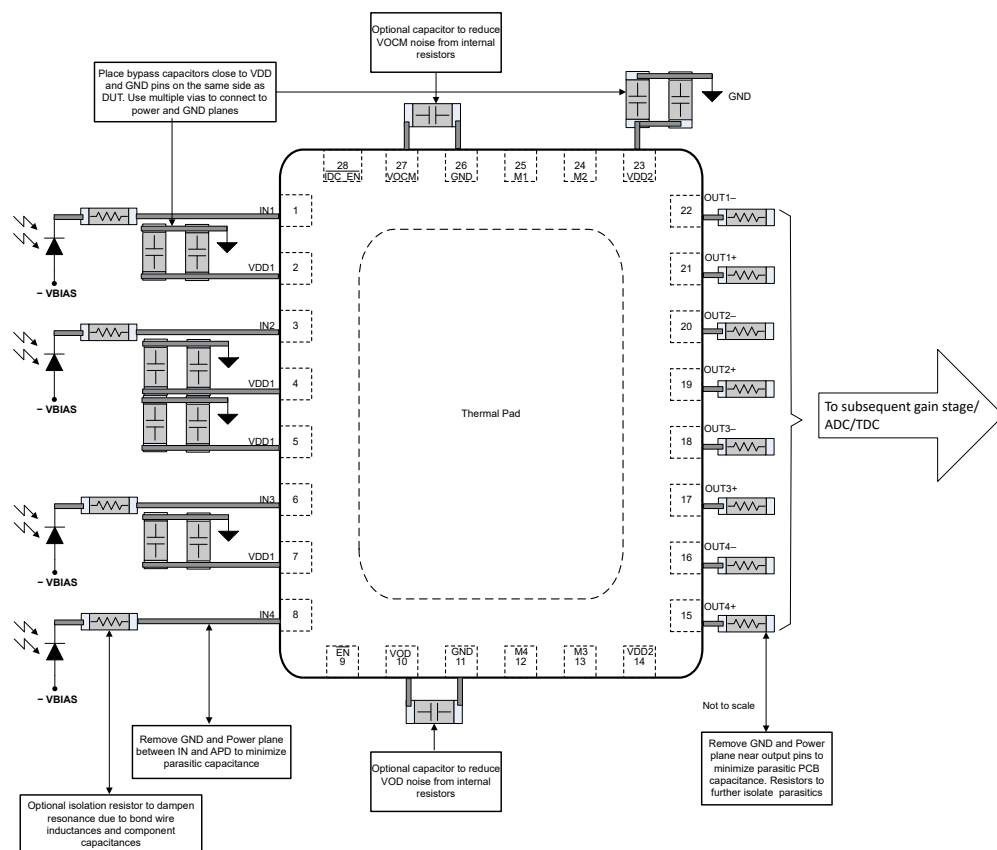


图 10-1. Layout Recommendation

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

- Texas Instruments, [LIDAR-Pulsed Time-of-Flight Reference Design design guide](#)
- Texas Instruments, [LIDAR-Pulsed Time-of-Flight Reference Design: Using High-Speed Data Converters design guide](#)
- Texas Instruments, [Optical Front-End System Reference Design design guide](#)

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [LMH32404 Evaluation Module user's guide](#)
- Texas Instruments, [Training Video: High speed TIAs for optical time of flight and LIDAR systems](#)
- Texas Instruments, [Training Video: Multi-channel optical front-end reference design overview](#)
- Texas Instruments, [Training Video: How to Convert a TINA-TI Model into a Generic SPICE Model](#)
- Texas Instruments, [Transimpedance Considerations for High-Speed Amplifiers application report](#)
- Texas Instruments, [What You Need To Know About Transimpedance Amplifiers – Part 1 blog](#)
- Texas Instruments, [What You Need To Know About Transimpedance Amplifiers – Part 2 blog](#)

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

11.5 Trademarks

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11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| LMH32404IRHFR | ACTIVE | VQFN | RHF | 28 | 3000 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 32404I | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LMH32404 :

- Automotive : [LMH32404-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LMH32404IRHFR | VQFN | RHF | 28 | 3000 | 330.0 | 12.4 | 4.3 | 5.3 | 1.3 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

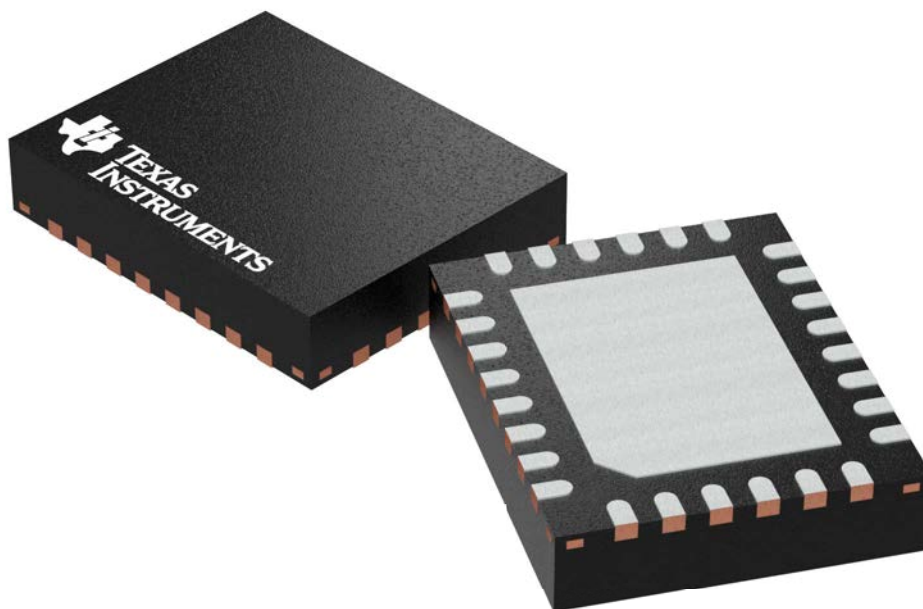
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMH32404IRHFR | VQFN | RHF | 28 | 3000 | 367.0 | 367.0 | 35.0 |

RHF 28

GENERIC PACKAGE VIEW

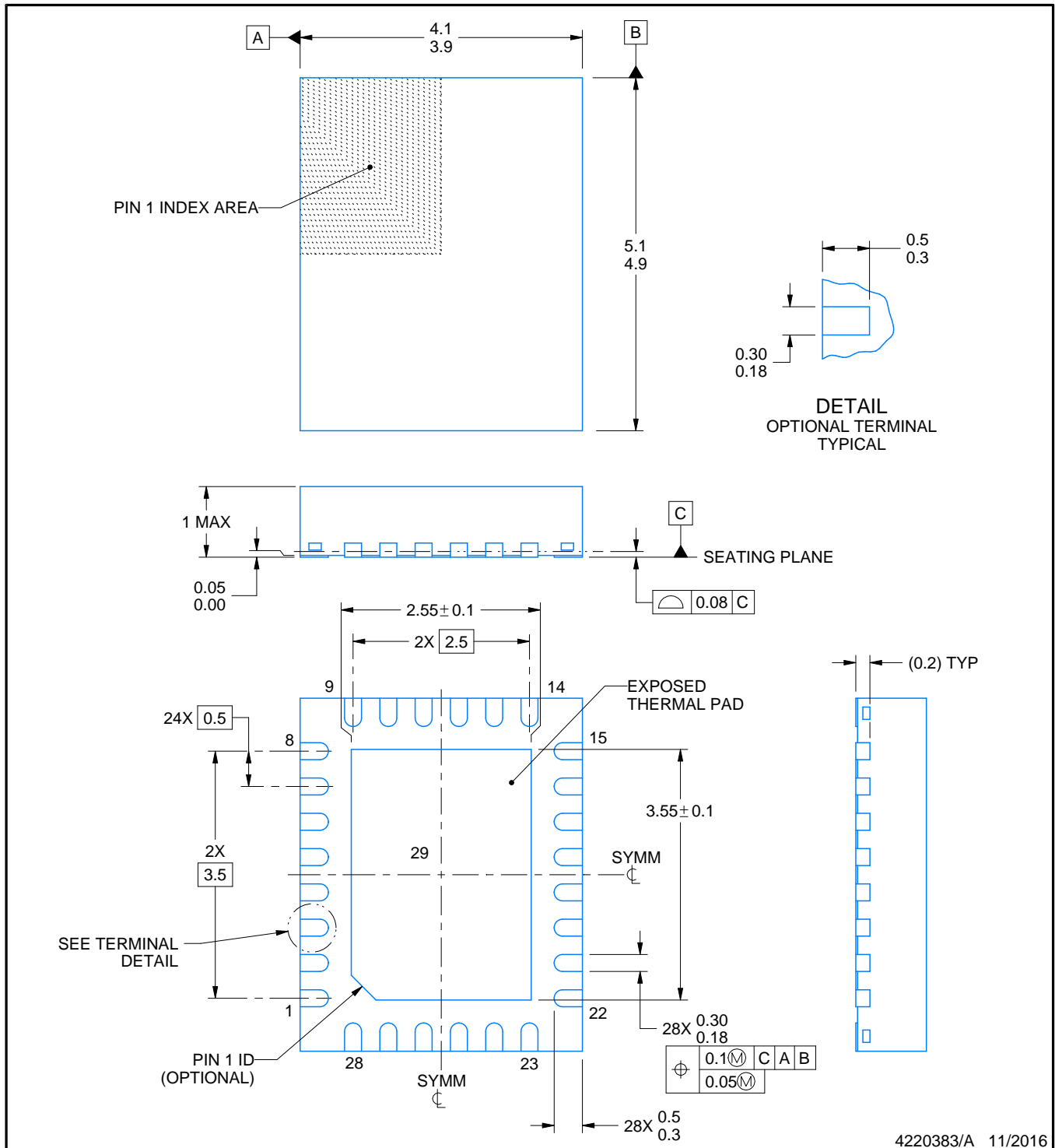
VQFN - 1.0 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4204845/J



NOTES:

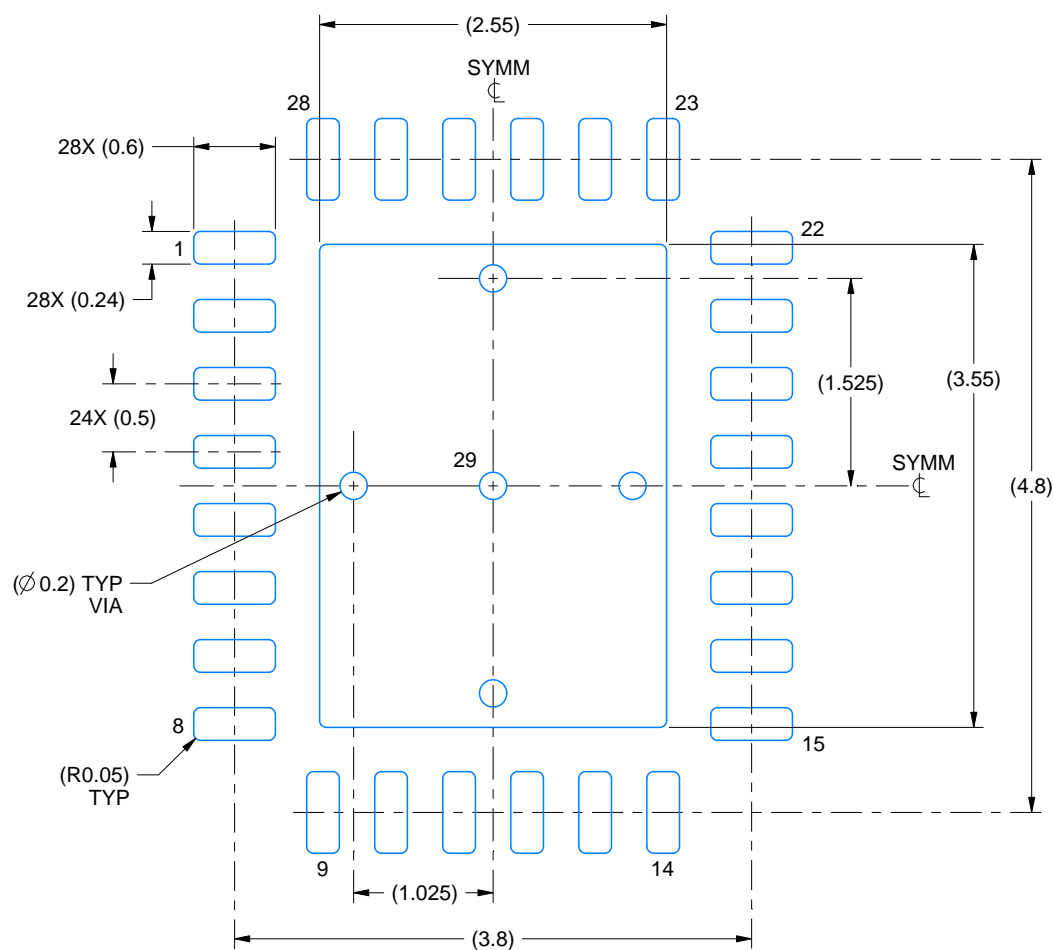
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

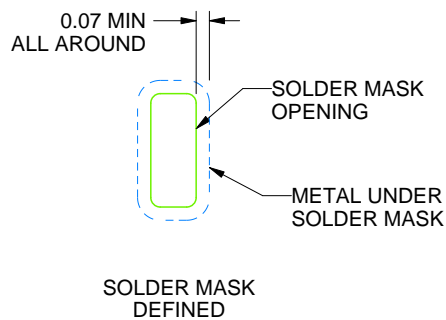
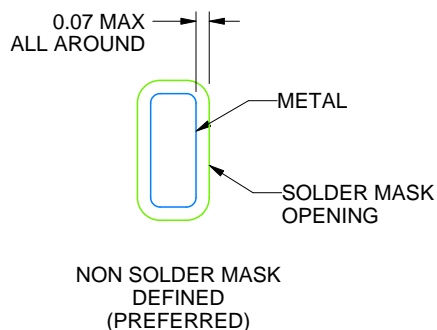
RHF0028A

VQFN - 1.0 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:18X



SOLDER MASK DETAILS

4220383/A 11/2016

NOTES: (continued)

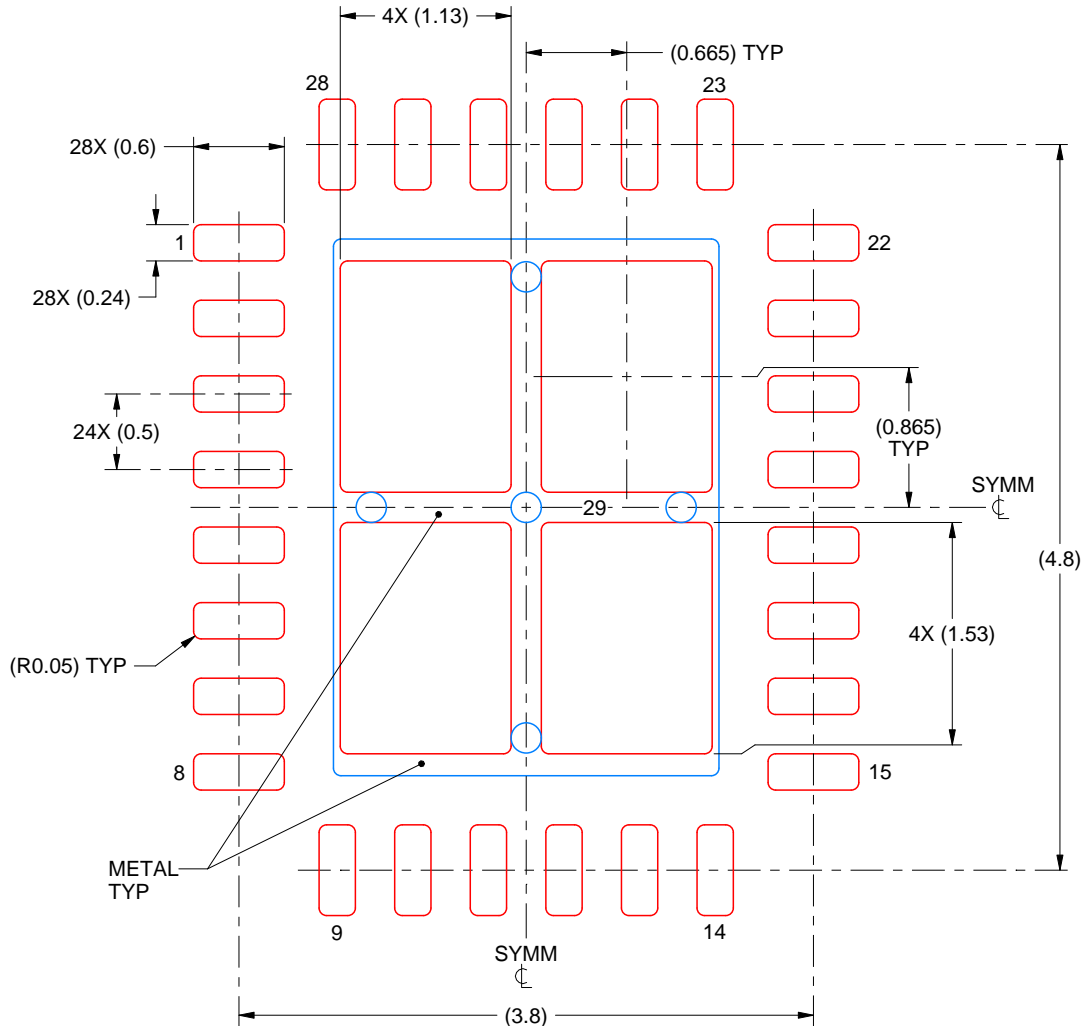
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RHF0028A

VQFN - 1.0 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 29
76% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:20X

4220383/A 11/2016

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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